

8-BIT SINGLE-CHIP MICROCOMPUTERS

DESCRIPTION

The μ PD78011BY, μ PD78012BY, μ PD78013Y and μ PD78014Y, μ PD78014Y sub-series products of the 78K/0 series, support the I²C bus control function. These computers incorporate various peripherals such as the serial interface (including I²C bus mode), 8-bit resolution A/D converter, timer, interrupt control, etc.

A one-time PROM or EPROM product, μ PD78P014Y, capable of operating in the same power supply voltage range as the mask ROM product is available. Development tools are also provided.

Functions are described in detail in the following User's Manual, which should be read when carrying out design work.

μ PD78014, 78014Y Series User's Manual : IEU-1343

FEATURES

- Serial Interface : 2 channels (compatible with I²C bus mode : 1 channel)
- ROM/RAM capacitance and package

Item Product Name	Program Memory (ROM)	Data Memory		Package
		Internal High-Speed RAM	Buffer RAM	
μ PD78011BY	8K bytes	512 bytes	32 bytes	<ul style="list-style-type: none"> • 64-pin Plastic Shrink DIP (750 mil) • 64-pin Plastic QFP (14 × 14 mm)
μ PD78012BY	16K bytes			
μ PD78013Y	24K bytes	1024 bytes		
μ PD78014Y	32K bytes			

- External memory expansion space: 64K bytes
- Instruction execution time can be varied from high-speed (0.4 μ s) to ultra-low-speed (122 μ s)
- I/O ports: 53 (N-ch open-drain : 4 included)
- 8-bit resolution A/D converter : 8 channels
- Timer: 5 channels
- Operating voltage range : 2.7 to 6.0 V

APPLICATION

Telephone, VCR, audio, camera, home appliances, etc.

The information in this document is subject to change without notice.

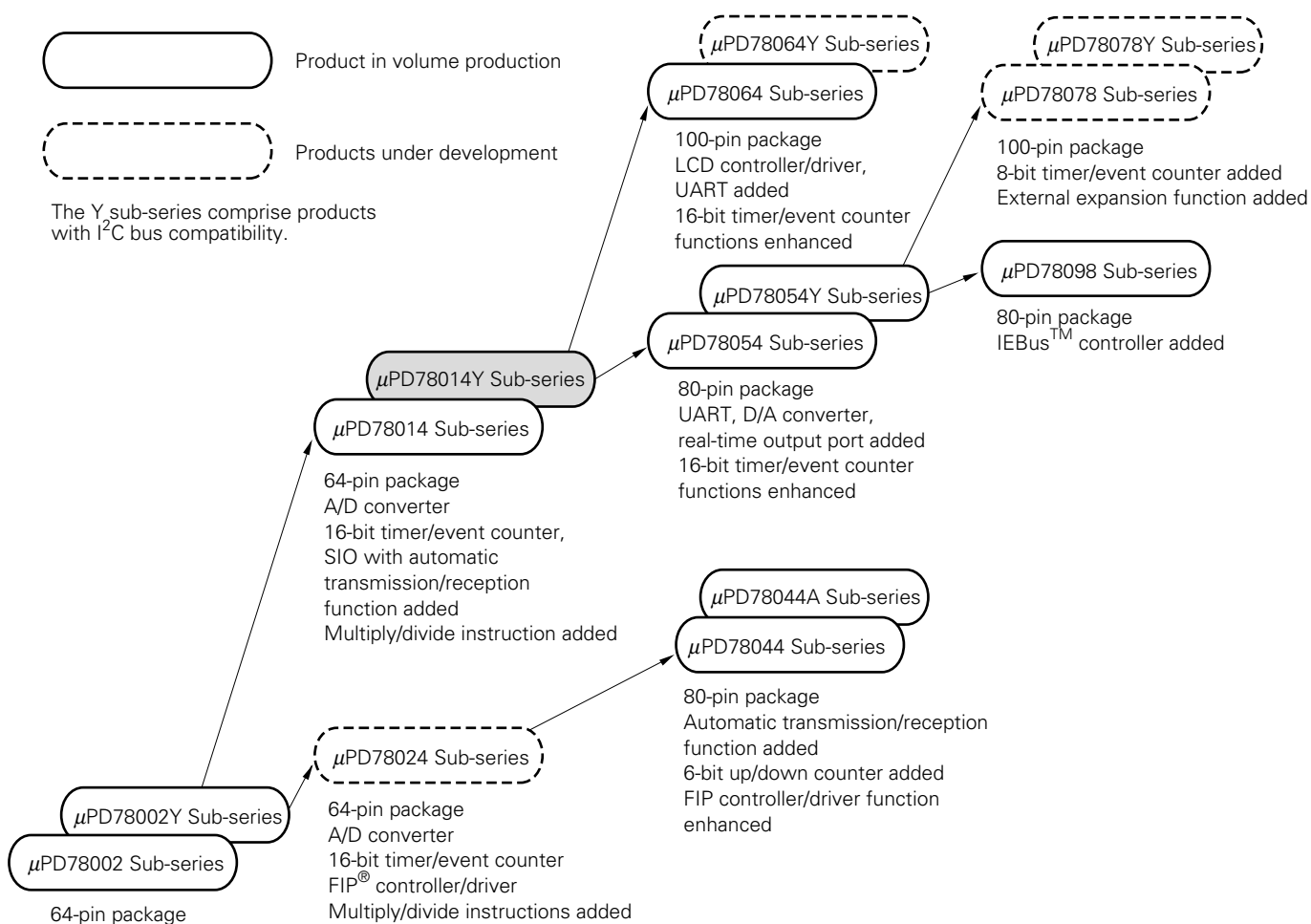
ORDERING INFORMATION

Ordering Code	Package	Quality Grade
μPD78011BYCW-xxx	64-pin plastic shrink DIP (750 mil)	Standard
μPD78011BYGC-xxx-AB8	64-pin plastic QFP (14 × 14 mm)	Standard
μPD78012BYCW-xxx	64-pin plastic shrink DIP (750 mil)	Standard
μPD78012BYGC-xxx-AB8	64-pin plastic QFP (14 × 14 mm)	Standard
μPD78013YCW-xxx	64-pin plastic shrink DIP (750 mil)	Standard
μPD78013YGC-xxx-AB8	64-pin plastic QFP (14 × 14 mm)	Standard
μPD78014YCW-xxx	64-pin plastic shrink DIP (750 mil)	Standard
μPD78014YGC-xxx-AB8	64-pin plastic QFP (14 × 14 mm)	Standard

Remark xxx means a ROM code number.

Please refer to “Quality grade on NEC Semiconductor Devices” (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

78K/0 SERIES DEVELOPMENT



OVERVIEW OF FUNCTION

Product Name		μPD78011BY	μPD78012BY	μPD78013Y	μPD78014Y
		Item			
Internal memory	ROM	8K bytes	16K bytes	24K bytes	32K bytes
	Internal high-speed RAM	512 bytes		1024 bytes	
	Buffer RAM	32 bytes			
Memory space		64K bytes			
General registers		8 bits × 32 registers (8 bits × 8 registers × 4 banks)			
Instruction cycle		On-chip instruction execution time cycle modification function			
	When main system clock selected	0.4 μs/0.8 μs/1.6 μs/3.2 μs/6.4 μs (at 10.0 MHz operation)			
	When subsystem clock selected	122 μs (at 32.768 kHz operation)			
Instruction set		<ul style="list-style-type: none"> • 16-bit operation • Multiplication/division (8 bits × 8 bits, 16 bits ÷ 8 bits) • Bit manipulation (set, reset, test, boolean operation) • BCD correction, etc. 			
I/O ports		Total : 53 <ul style="list-style-type: none"> • CMOS input : 2 • CMOS I/O : 47 • N-channel open-drain I/O (15 V withstand voltage) : 4 			
A/D converter		<ul style="list-style-type: none"> • 8-bit resolution × 8 channels • Operable over a wide power supply voltage range: V_{DD} = 2.7 to 6.0 V 			
Serial interface		<ul style="list-style-type: none"> • 3-wire/SBI/2-wire/I²C bus mode selectable: 1 channel • 3-wire mode (on-chip max. 32 bytes automatic data transmit/receive function): 1 channel 			
Timer		<ul style="list-style-type: none"> • 16-bit timer/event counter : 1 channel • 8-bit timer/event counter : 2 channels • Watch timer : 1 channel • Watchdog timer : 1 channel 			
Timer output		3 (14-bit PWM output × 1)			
Clock output		39.1 kHz, 78.1 kHz, 156 kHz, 313 kHz, 625 kHz, 1.25 MHz (at main system clock 10.0 MHz operation), 32.768 kHz (at subsystem clock 32.768 kHz operation)			
Buzzer output		2.4 kHz, 4.9 kHz, 9.8 kHz (at main system clock 10.0 MHz operation)			
Vectored interrupts	Maskable interrupts	Internal : 8 External : 4			
	Non-maskable interrupt	Internal : 1			
	Software interrupt	Internal : 1			
Test input		Internal : 1 External : 1			
Operating voltage range		V _{DD} = 2.7 to 6.0 V			
Operating temperature range		-40 to +85°C			
Package		<ul style="list-style-type: none"> • 64-pin plastic shrink DIP (750 mil) • 64-pin plastic QFP (14 × 14 mm) 			

CONTENTS

1. PIN CONFIGURATION (TOP VIEW)5

2. BLOCK DIAGRAM8

3. PIN FUNCTION LIST9

3.1 PORT PINS9

3.2 NON-PORT PINS11

3.3 PIN I/O CIRCUITS AND RECOMMENDED CONNECTION OF UNUSED PINS13

4. MEMORY SPACE16

5. CHARACTERISTIC OF PERIPHERAL HARDWARE FUNCTIONS17

5.1 PORTS17

5.2 CLOCK GENERATOR18

5.3 TIMER/EVENT COUNTER18

5.4 CLOCK OUTPUT CONTROL CIRCUIT21

5.5 BUZZER OUTPUT CONTROL CIRCUIT21

5.6 A/D CONVERTER22

5.7 SERIAL INTERFACES23

6. INTERRUPT FUNCTIONS AND TEST FUNCTIONS25

6.1 INTERRUPT FUNCTIONS25

6.2 TEST FUNCTIONS28

7. EXTERNAL DEVICE EXPANSION FUNCTIONS29

8. STANDBY FUNCTION29

9. RESET FUNCTION29

10. INSTRUCTION SET30

11. ELECTRICAL SPECIFICATIONS32

12. CHARACTERISTIC CURVE (REFERENCE VALUES)57

13. PACKAGE DRAWINGS62

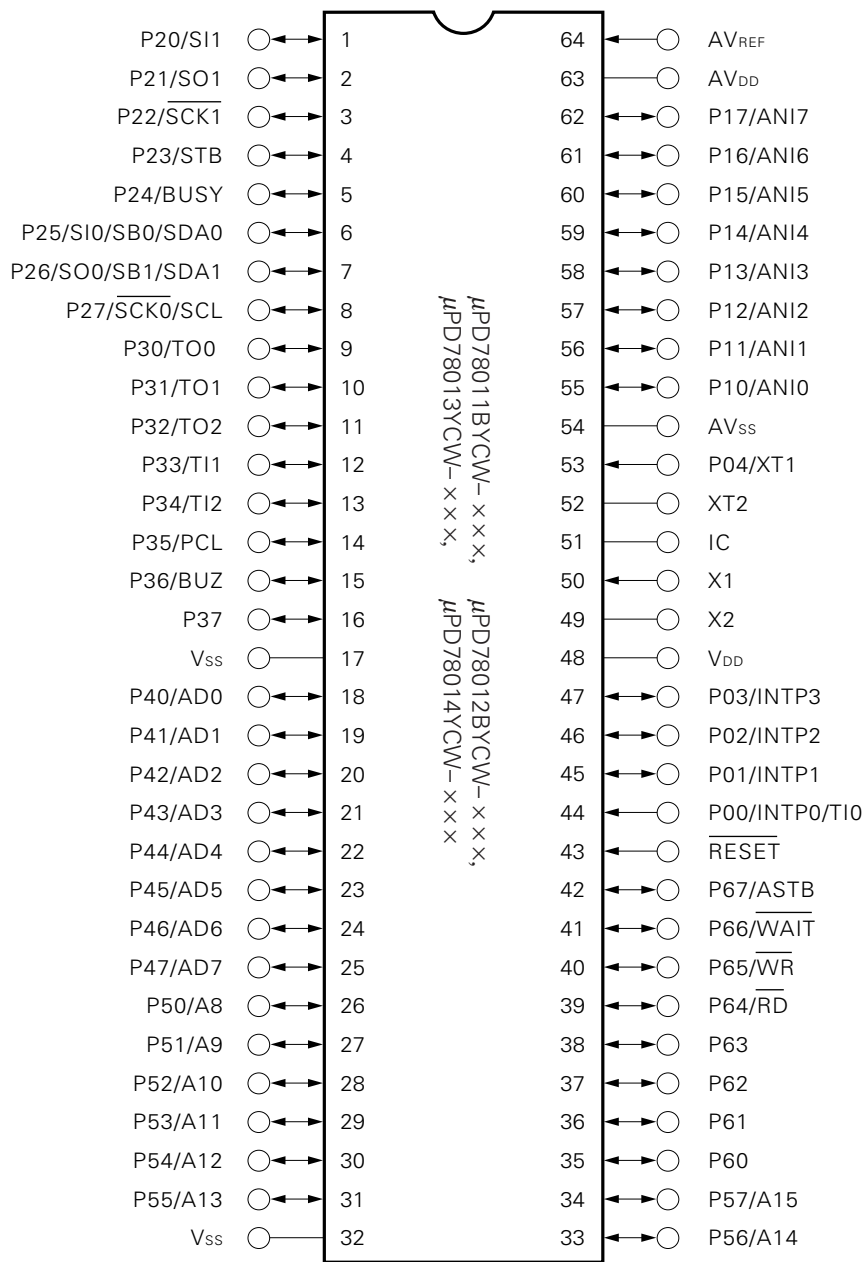
14. RECOMMENDED SOLDERING CONDITIONS66

APPENDIX A. DEVELOPMENT TOOLS68

APPENDIX B. RELATED DOCUMENTATION69

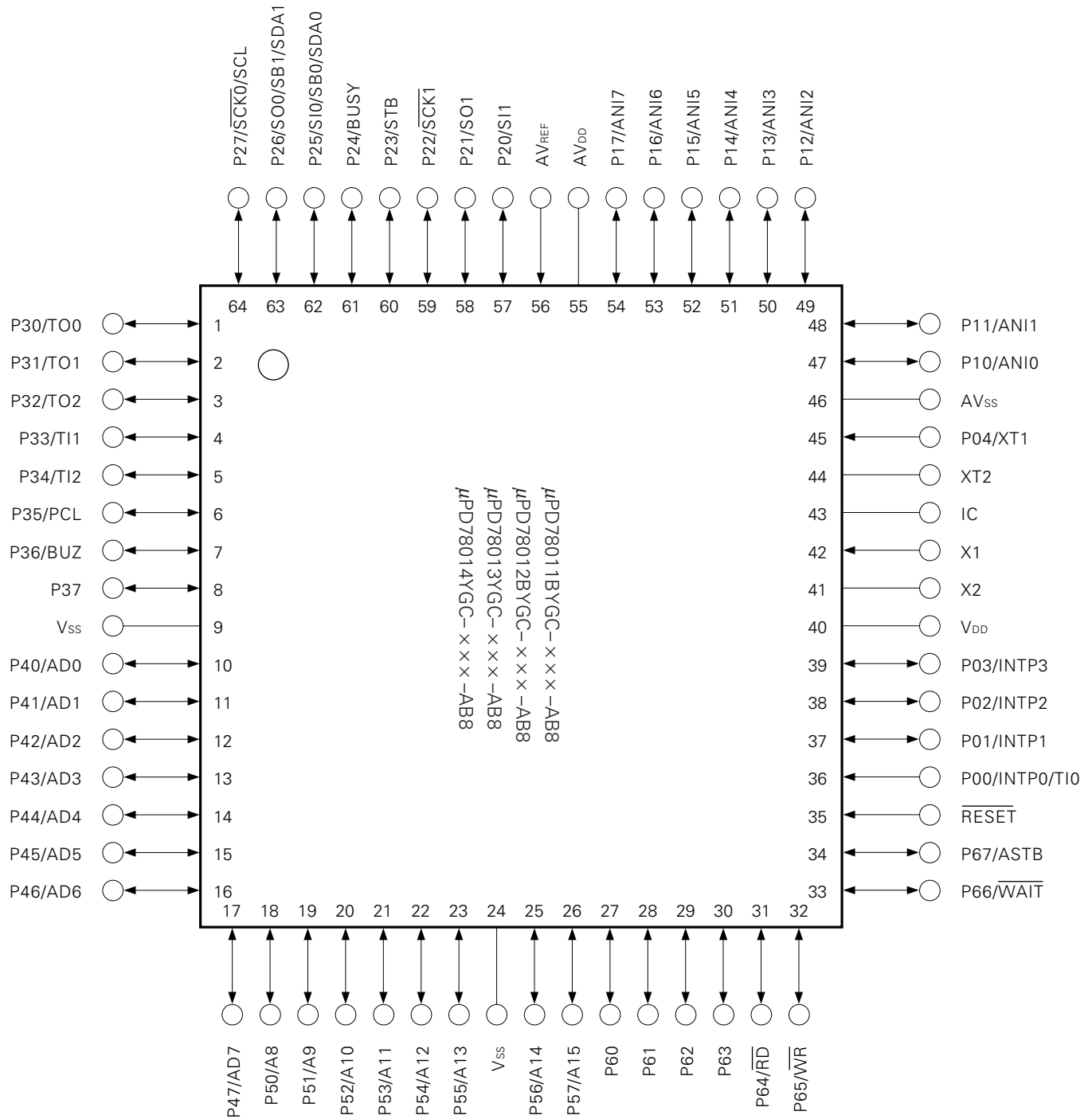
1. PIN CONFIGURATION (TOP VIEW)

64-Pin Plastic Shrink DIP (750 mil)



- Cautions**
1. Always connect the IC (Internally Connected) pin to V_{SS}.
 2. Always connect the AV_{DD} pin to V_{DD}.
 3. Always connect the AV_{SS} pin to V_{SS}.

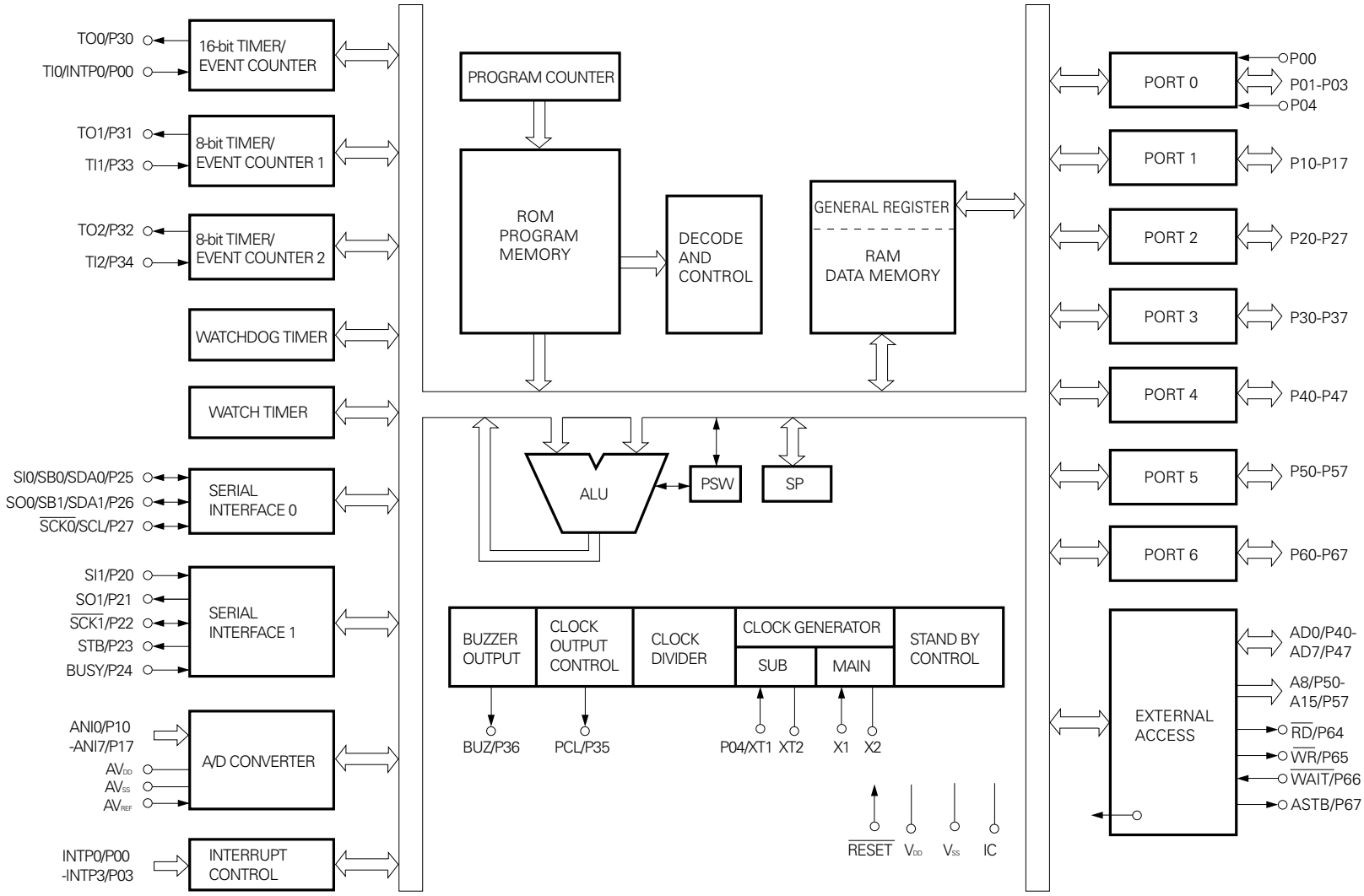
64-Pin Plastic QFP (14 × 14 mm)



- Cautions**
1. Always connect the IC (Internally Connected) pin to V_{SS}.
 2. Always connect the AV_{DD} pin to V_{DD}.
 3. Always connect the AV_{SS} pin to V_{SS}.

P00 to P04	: Port 0	AD0 to AD7	: Address/Data Bus
P10 to P17	: Port 1	A8 to A15	: Address Bus
P20 to P27	: Port 2	\overline{RD}	: Read Strobe
P30 to P37	: Port 3	\overline{WR}	: Write Strobe
P40 to P47	: Port 4	\overline{WAIT}	: Wait
P50 to P57	: Port 5	ASTB	: Address Strobe
P60 to P67	: Port 6	X1, X2	: Crystal (Main System Clock)
INTP0 to INTP3	: Interrupt From Peripherals	XT1, XT2	: Crystal (Subsystem Clock)
TI0 to TI2	: Timer Input	\overline{RESET}	: Reset
TO0 to TO2	: Timer Output	ANI0 to ANI7	: Analog Input
SB0, SB1	: Serial Bus	AV_{DD}	: Analog Power Supply
SI0, SI1	: Serial Input	AV_{SS}	: Analog Ground
SO0, SO1	: Serial Output	AV_{REF}	: Analog Reference Voltage
$\overline{SCK0}, \overline{SCK1}$: Serial Clock	V_{DD}	: Power Supply
SCL	: Serial Clock	V_{SS}	: Ground
SDA0, SDA1	: Serial Data	IC	: Internally Connected
PCL	: Programmable Clock		
BUZ	: Buzzer Clock		
STB	: Strobe		
BUSY	: Busy		

2. BLOCK DIAGRAM



Remark Internal ROM & RAM capacity varies depending on the product.

3. PIN FUNCTION LIST

3.1 PORT PINS (1/2)

Pin Name	I/O	Function		At Reset	Dual-Function Pin
P00	Input	Port 0 5-bit I/O port	Input only	Input	INTP0/TI0
P01	Input/ output		Input/output can be specified in bit-wise. When used as an input port, pull-up resistor can be used by software.	Input	INTP1
P02					INTP2
P03					INTP3
P04 ^{Note 1}	Input		Input only	Input	XT1
P10 to P17	Input/ output	Port 1 8-bit input/output port. Input/output can be specified in bit-wise. When used as an input port, pull-up resistor can be used by software. ^{Note 2}		Input	ANI0 to ANI7
P20	Input/ output	Port 2 8-bit input/output port. Input/output can be specified in bit-wise. When used as an input port, pull-up resistor can be used by software.	Input/output can be specified in bit-wise. When used as an input port, pull-up resistor can be used by software.	Input	SI1
P21					SO1
P22					$\overline{\text{SCK1}}$
P23					STB
P24					BUSY
P25					SI0/SB0/SDA0
P26					SO0/SB1/SDA1
P27					$\overline{\text{SCK0/SCL}}$
P30	Input/ output	Port 3 8-bit input/output port. Input/output can be specified in bit-wise. When used as an input port, pull-up resistor can be used by software.	Input/output can be specified in bit-wise. When used as an input port, pull-up resistor can be used by software.	Input	TO0
P31					TO1
P32					TO2
P33					TI1
P34					TI2
P35					PCL
P36					BUZ
P37					—
P40 to P47	Input/ output	Port 4 8-bit input/output port. Input/output can be specified in 8-bit unit. When used as an input port, pull-up resistor can be used by software. Test input flag (KRIF) is set to 1 by falling edge detection.		Input	AD0 to AD7

- Notes**
1. When using the P04/XT1 pins as an input port, do not use the on-chip feedback resistor of the subsystem clock oscillator with bit 6 (FRC) of the processor control register set to 1.
 2. When using the P10/ANI0 to P17/ANI7 pins as the A/D converter analog input, pull-up resistor is automatically unused.

3.1 PORT PINS (2/2)

Pin Name	I/O	Function		At Reset	Dual-Function Pin
P50 to P57	Input/output	Port 5 8-bit input/output port. LED can be driven directly. Input/output can be specified in bit-wise. When used as an input port, pull-up resistor can be used by software.		Input	A8 to A15
P60	Input/output	Port 6 8-bit input/output port. Input/output can be specified in bit-wise.	N-ch open-drain input/output port. On-chip pull-up resistor can be specified by mask option. LED can be driven directly.	Input	—
P61					
P62					
P63					
P64			When used as an input port, pull-up resistor can be used by software.		\overline{RD}
P65					\overline{WR}
P66					\overline{WAIT}
P67					ASTB

Caution Non-use of pull-up resistor (specified by mask option) increases low-level input leakage current by $-200 \mu\text{A}$ (MAX.) in either of the following cases:

- ① When the low-level input is performed to the pin using the external device expansion function.
- ② For 3-clock cycle when the port 6 (P6)/port mode register (PM6) read instruction execution is performed.

3.2 NON-PORT PINS (1/2)

Pin Name	I/O	Function	At Reset	Dual-Function Pin
INTP0	Input	External interrupt input by which the effective edge (rising edge, falling edge, or both rising edge and falling edge) can be specified.	Input	P00/TI0
INTP1				P01
INTP2				P02
INTP3				Falling edge detection external interrupt input
SI0	Input	Serial interface serial data input	Input	P25/SB0/SDA0
SI1				P20
SO0	Output	Serial interface serial data output	Input	P26/SB1/SDA1
SO1				P21
SB0	Input/output	Serial interface serial data input/output	Input	P25/SI0/SDA0
SB1				P26/SO0/SDA1
SDA0				P25/SI0SB0
SDA1				P26/SO0/SB1
$\overline{\text{SCK0}}$	Input/output	Serial interface serial clock input/output	Input	P27/SCL
SCL				P27/ $\overline{\text{SCK0}}$
$\overline{\text{SCK1}}$				P22
STB	Output	Serial interface automatic transmit/receive strobe output	Input	P23
BUSY	Input	Serial interface automatic transmit/receive busy input	Input	P24
TI0	Input	External count clock input to 16-bit timer (TM0)	Input	P00/INTP0
TI1		External count clock input to 8-bit timer (TM1)		P33
TI2		External count clock input to 8-bit timer (TM2)		P34
TO0	Output	16-bit timer (TM0) output (shared as 14-bit PWM output)	Input	P30
TO1		8-bit timer (TM1) output		P31
TO2		8-bit timer (TM2) output		P32
PCL	Output	Clock output (for main system clock, subsystem clock trimming)	Input	P35
BUZ	Output	Buzzer output	Input	P36
AD0 to AD7	Input/output	Low-order address/data bus at external memory expansion	Input	P40 to P47
A8 to A15	Output	High-order address bus at external memory expansion	Input	P50 to P57
$\overline{\text{RD}}$	Output	External memory read operation strobe signal output	Input	P64
$\overline{\text{WR}}$		External memory write operation strobe signal output		P65
$\overline{\text{WAIT}}$	Input	Wait insertion at external memory access	Input	P66
ASTB	Output	Strobe output which latches the address information output at ports 4 and 5 to access external memory	Input	P67

3.2 NON-PORT PINS (2/2)

Pin Name	I/O	Function	At Reset	Dual-Function Pin
ANI0 to ANI7	Input	A/D converter analog input	Input	P10 to P17
AVREF	Input	A/D converter reference voltage input	—	—
AVDD	—	A/D converter analog power supply. Connected to V _{DD} .	—	—
AVss	—	A/D converter ground potential. Connected to V _{ss} .	—	—
$\overline{\text{RESET}}$	Input	System reset input	—	—
X1	Input	Main system clock oscillation crystal connection	—	—
X2	—		—	—
XT1	Input	Subsystem clock oscillation crystal connection	Input	P04
XT2	—		—	—
VDD	—	Positive power supply	—	—
Vss	—	Ground potential	—	—
IC	—	Internal connection. Connected directly to V _{ss} .	—	—

3.3 PIN I/O CIRCUITS AND RECOMMENDED CONNECTION OF UNUSED PINS

The input/output circuit type of each pin and recommended connection of unused pins are shown in Table 3-1.

For the input/output circuit configuration of each type, see Fig. 3-1.

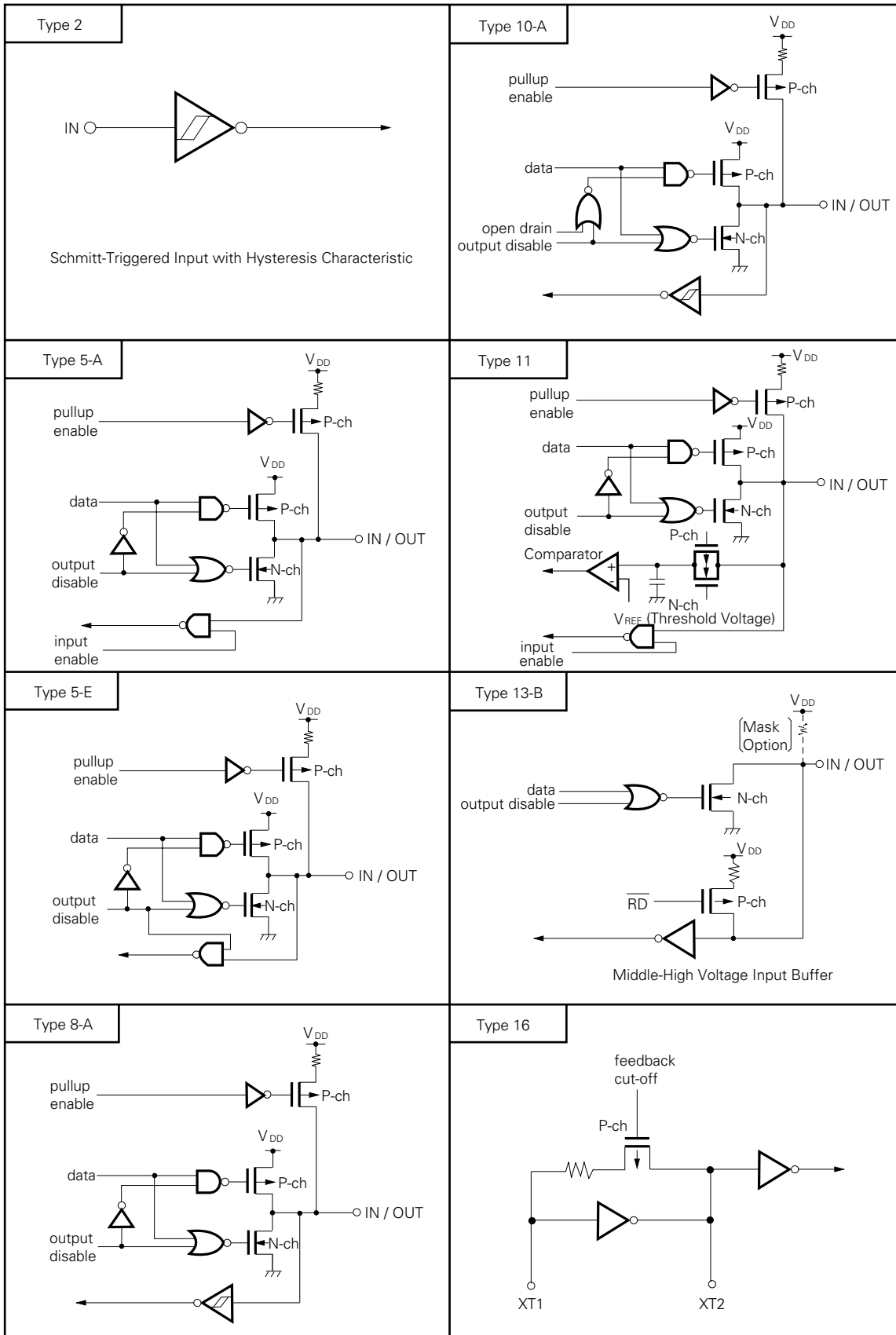
Table 3-1 Input/Output Circuit Type of Each Pin (1/2)

Pin Name	Input/output Circuit Type	I/O	Recommended Connection when not Used		
P00/INTP0/TI0	2	Input	Connected to Vss .		
P01/INTP1	8-A	Input/output	Input : Connected to Vss .		
P02/INTP2			Output : Leave open.		
P03/INTP3					
P04/XT1	16	Input	Connected to Vss .		
P10/ANI0 to P17/ANI7	11	Input/output	Input : Connected to VDD or Vss . Output : Leave open.		
P20/SI1	8-A	Input/output	Input : Connected to VDD or Vss . Output : Leave open.		
P21/SO1	5-A				
P22/SCK1	8-A				
P23/STB	5-A				
P24/BUSY	8-A				
P25/SI0/SB0/SDA0	10-A				
P26/SO0/SB1/SDA1					
P27/SCK0/SCL					
P30/TO0	5-A	Input/output	Input : Connected to VDD or Vss . Output : Leave open.		
P31/TO1					
P32/TO2					
P33/TI1	8-A	Input/output	Input : Connected to VDD or Vss . Output : Leave open.		
P34/TI2					
P35/PCL	5-A				
P36/BUZ					
P37					
P40/AD0 to P47/AD7				5-E	
P50/A8 to P57/A15	5-A			Input/output	Input : Connected to VDD or Vss . Output : Leave open.
P60 to P63	13-B				
P64/RD	5-A				
P65/WR					
P66/WAIT					
P67/ASTB					

Table 3-1 Input/Output Circuit Type of Each Pin (2/2)

Pin Name	Input/output Circuit Type	I/O	Recommended Connection when not Used
RESET	2	Input	—
XT2	16	—	Leave open.
AVREF	—		Connected to Vss .
AVDD			Connected to VDD .
AVSS			Connected to Vss .
IC			Connected directly to Vss .

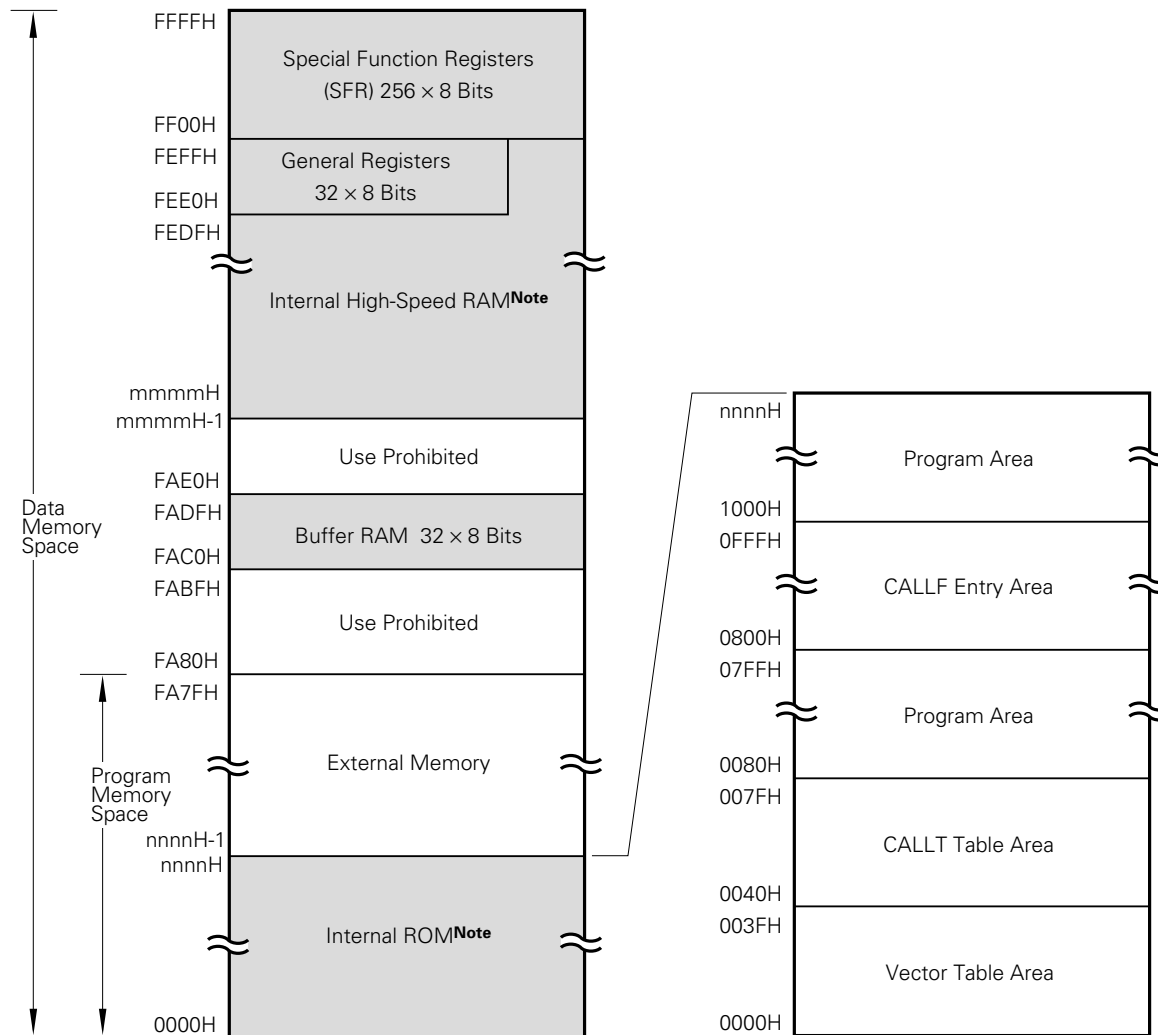
Fig. 3-1 Pin Input/Output Circuits



4. MEMORY SPACE

Memory map of μPD78011BY, μPD78012BY, μPD78013Y and μPD78014Y is shown in Table 4-1.

Fig. 4-1 Memory Map



Remark Shaded area indicates internal memory.

Note Internal ROM/internal high-speed RAM capacitance depends on product (See the table below).

Product Name	Internal ROM End Address nnnnH	Internal High-Speed RAM Initial Address mmmmH
μPD78011BY	1FFFH	FB00H
μPD78012BY	3FFFH	
μPD78013Y	5FFFH	
μPD78014Y	7FFFH	

5. CHARACTERISTICS OF PERIPHERAL HARDWARE FUNCTIONS

5.1 PORTS

The following 3 I/O ports are set:

• CMOS input (P00, P04)	: 2
• CMOS input/output (P01 to P03, port 1 to port 5, P64 to P67)	: 47
• N-ch open-drain input/output (15 V withstand voltage)(P60 to P63)	: 4
<hr/>	
Total	: 53

Table 5-1 Functions of Ports

Name	Pin Name	Function
Port 0	P00, P04	Input only port
	P01 to P03	I/O port. I/O specifiable bit-wise. When used as an input port, internal pull-up resistor can be used by software.
Port 1	P10 to P17	I/O port. I/O specifiable bit-wise. When used as an input port, internal pull-up resistor can be used by software.
Port 2	P20 to P27	I/O port. I/O specifiable bit-wise. When used as an input port, internal pull-up resistor can be used by software.
Port 3	P30 to P37	I/O port. I/O specifiable bit-wise. When used as an input port, internal pull-up resistor can be used by software.
Port 4	P40 to P47	I/O port. I/O specifiable in 8-bit unit. When used as an input port, internal pull-up resistor can be used by software. Test input flag (KRIF) is set to 1 by falling edge detection.
Port 5	P50 to P57	I/O port. I/O specifiable bit-wise. When used as an input port, internal pull-up resistor can be used by software. LED can be driven directly.
Port 6	P60 to P63	N-ch open-drain I/O port. I/O specifiable bit-wise. Pull-up resistor can be incorporated by mask option. LED can be driven directly.
	P64 to P67	I/O port. I/O specifiable bit-wise. When used as an input port, internal pull-up resistor can be used by software.

Caution Non-use of pull-up resistor (specified by mask option) increases low-level input leakage current by $-200\mu\text{A}$ (MAX.) in either of the following cases:

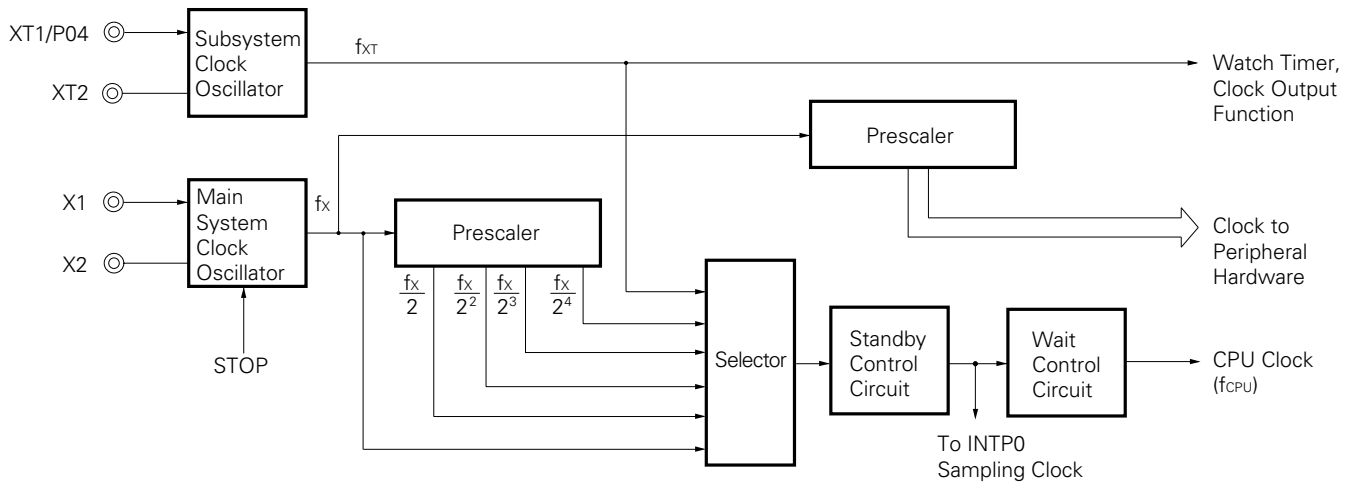
- ① **When the low-level input is performed to the pin using the external device expansion function is used.**
- ② **For 3-clock cycle when the port6 (P6)/port mode register (PM6) read instruction execution is performed.**

5.2 CLOCK GENERATOR

Clock generator includes main system clock generator and subsystem clock generator and can also change instruction execution time.

- 0.4 μs/0.8 μs/1.6 μs/3.2 μs/6.4 μs (Main system clock: operation at 10.0 MHz)
- 122 μs (Subsystem clock: operation at 32.768 kHz)

Fig. 5-1 Clock Generator Block Diagram



5.3 TIMER/EVENT COUNTER

5 channels of timer/event counters are incorporated.

- 16-bit timer/event counter : 1 channel
- 8-bit timer/event counter : 2 channels
- Watch timer : 1 channel
- Watchdog timer : 1 channel

Table 5-2 Type And Function of Timer/Event Counter

		16-bit Timer/Event Counter	8-bit Timer/Event Counter	Watch Timer	Watchdog Timer
Type	Interval timer	1 channel	2 channels	1 channel	1 channel
	External event counter	1 channel	2 channels	—	—
Function	Timer output	1 output	2 outputs	—	—
	PWM output	1 output	—	—	—
	Pulse width measurement	1 input	—	—	—
	Square-wave output	1 output	2 outputs	—	—
	Interrupt request	2	2	2	1

Fig. 5-2 16-bit Timer/Event Counter Block Diagram

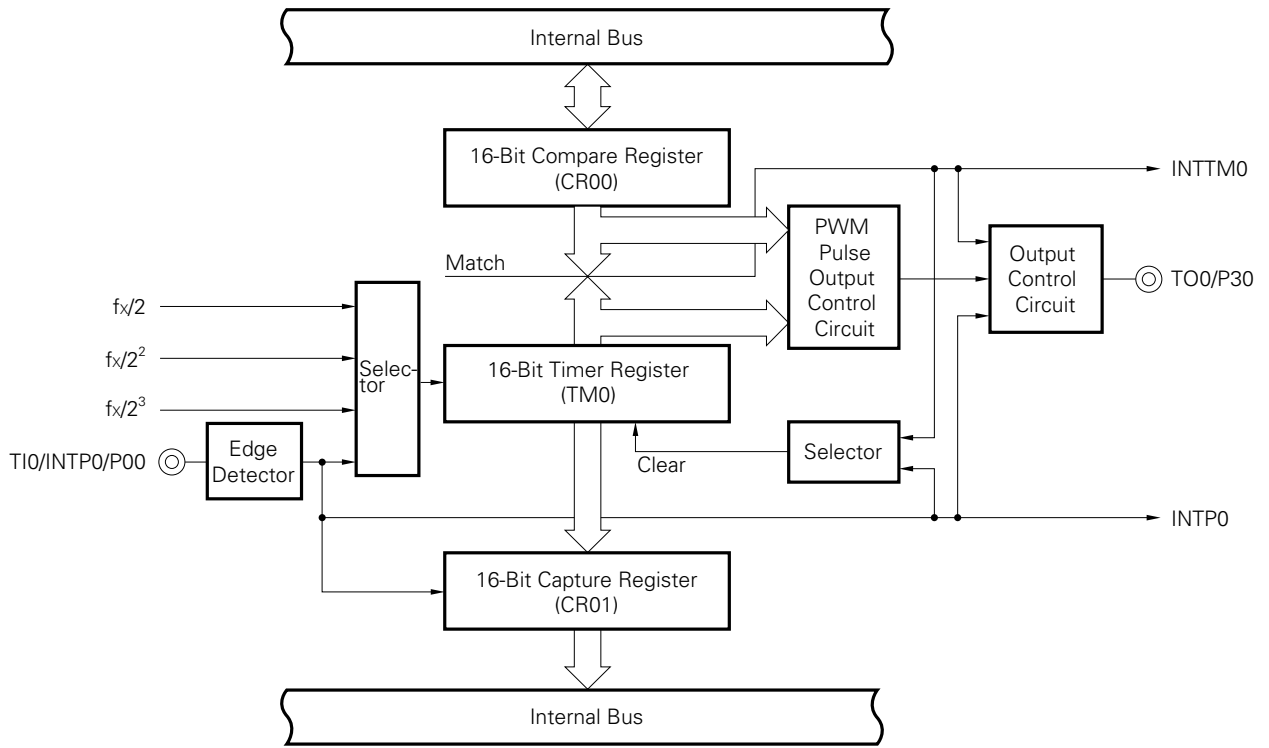


Fig. 5-3 8-Bit Timer/Event Counter Block Diagram

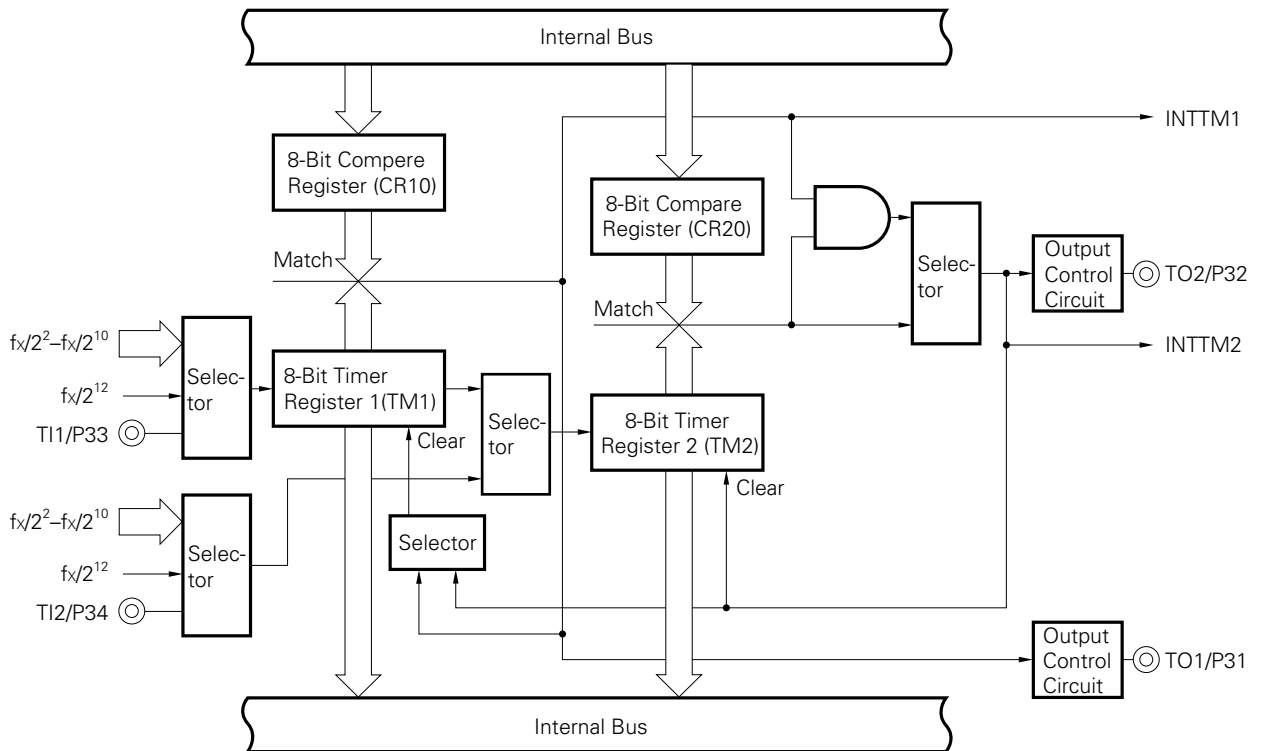


Fig. 5-4 Watch Timer Block Diagram

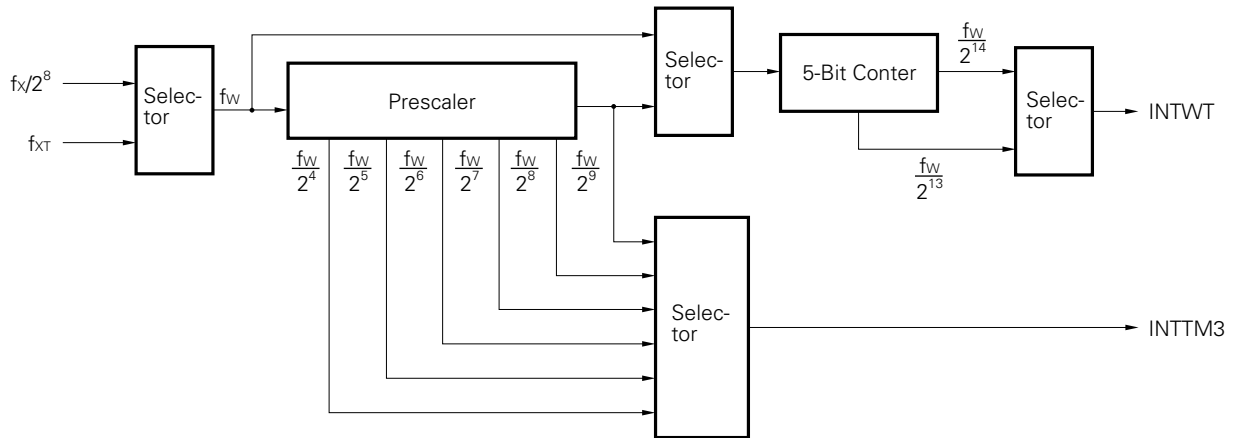
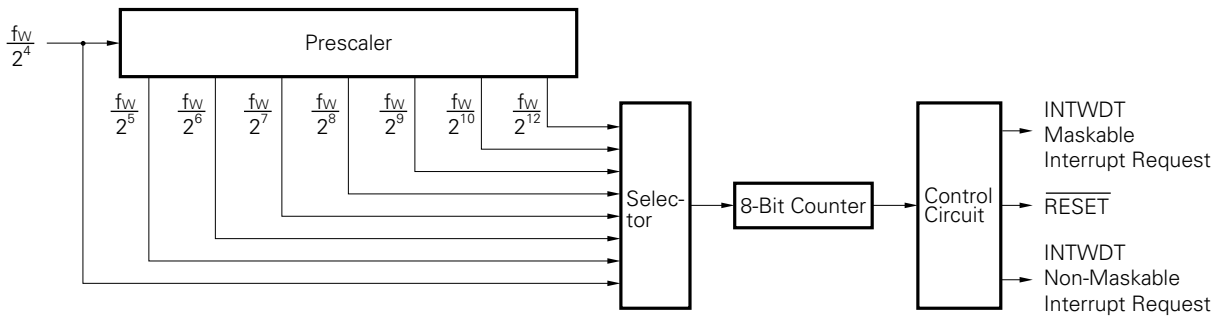


Fig. 5-5 Watchdog Timer Block Diagram

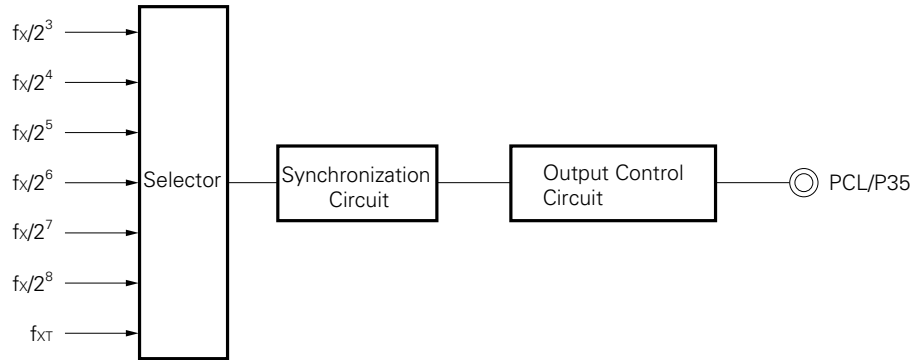


5.4 CLOCK OUTPUT CONTROL CIRCUIT

The following frequency clocks can be output as clock output:

- 39.1 kHz/78.1 kHz/156 kHz/313 kHz/625 kHz/1.25 MHz
(Main system clock : operation at 10.0 MHz)
- 32.768 kHz
(Subsystem clock : operation at 32.768 kHz)

Fig. 5-6 Clock Output Control Circuit Block Diagram

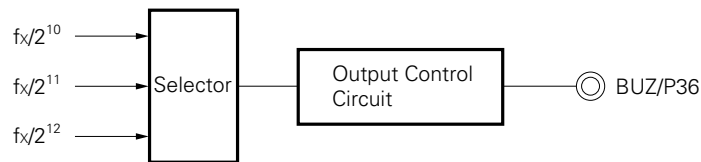


5.5 BUZZER OUTPUT CONTROL CIRCUIT

The following frequency clocks can be output as buzzer output:

- 2.4 kHz/4.9 kHz/9.8 kHz
(Main system clock : operation at 10.0 MHz)

Figure 5-7 Buzzer Output Control Circuit Block Diagram



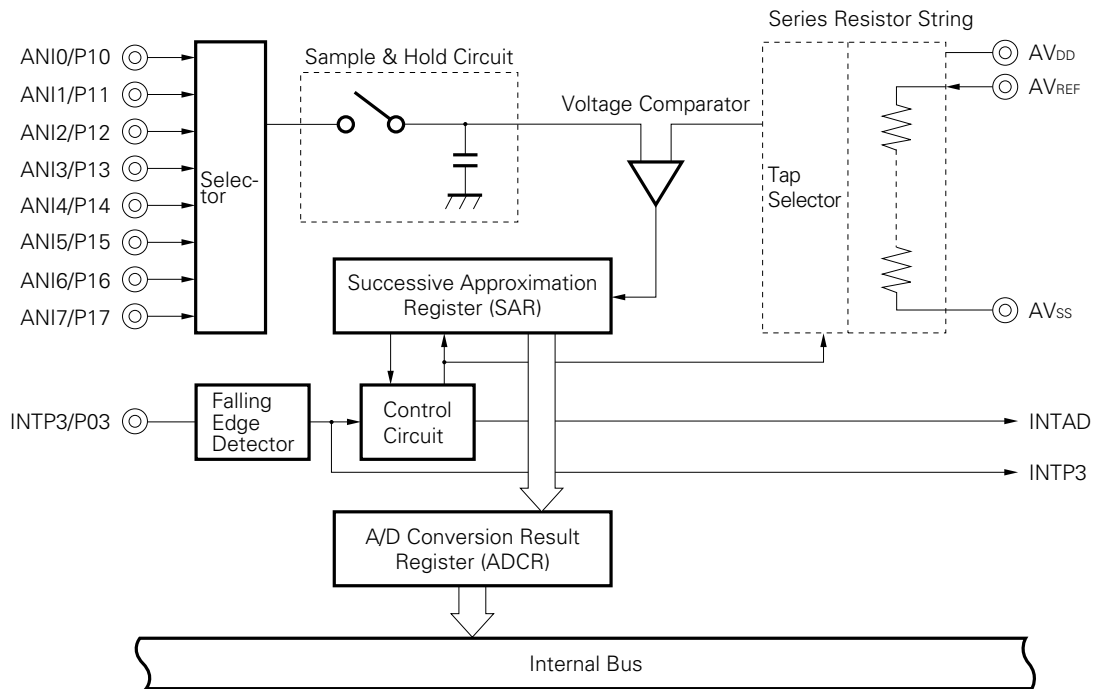
5.6 A/D CONVERTER

8-bit resolution 8-channel A/D converter is incorporated.

The following 2 start methods are set for A/D conversion operation.

- Hardware start
- Software start

Fig. 5-8 A/D Converter Block Diagram



5.7 SERIAL INTERFACES

2 channels of clocked serial interface are incorporated.

- Serial interface channel 0
- Serial interface channel 1

Table 5-3 Type And Function of Serial Interface

Function	Serial interface channel 0	Serial interface channel 1
3 wires serial I/O mode	o (MSB/LSB start switchable)	o (MSB/LSB start switchable)
3 wires serial I/O mode with automatic transmission/reception function	—	o (MSB/LSB start switchable)
SBI (Serial bus interface) mode	o (MSB start)	—
2 wires serial I/O mode	o (MSB start)	—
I ² C (Inter IC) bus mode	o (MSB start)	—

Fig. 5-9 Serial Interface Channel 0 Block Diagram

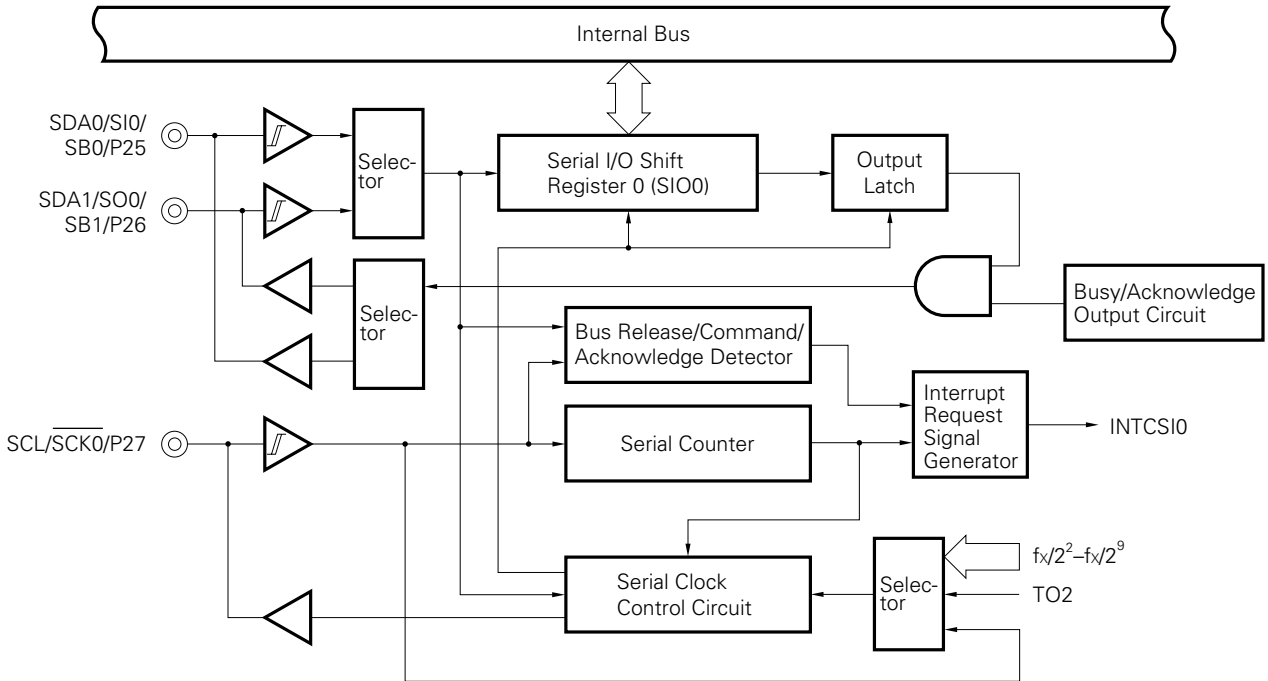
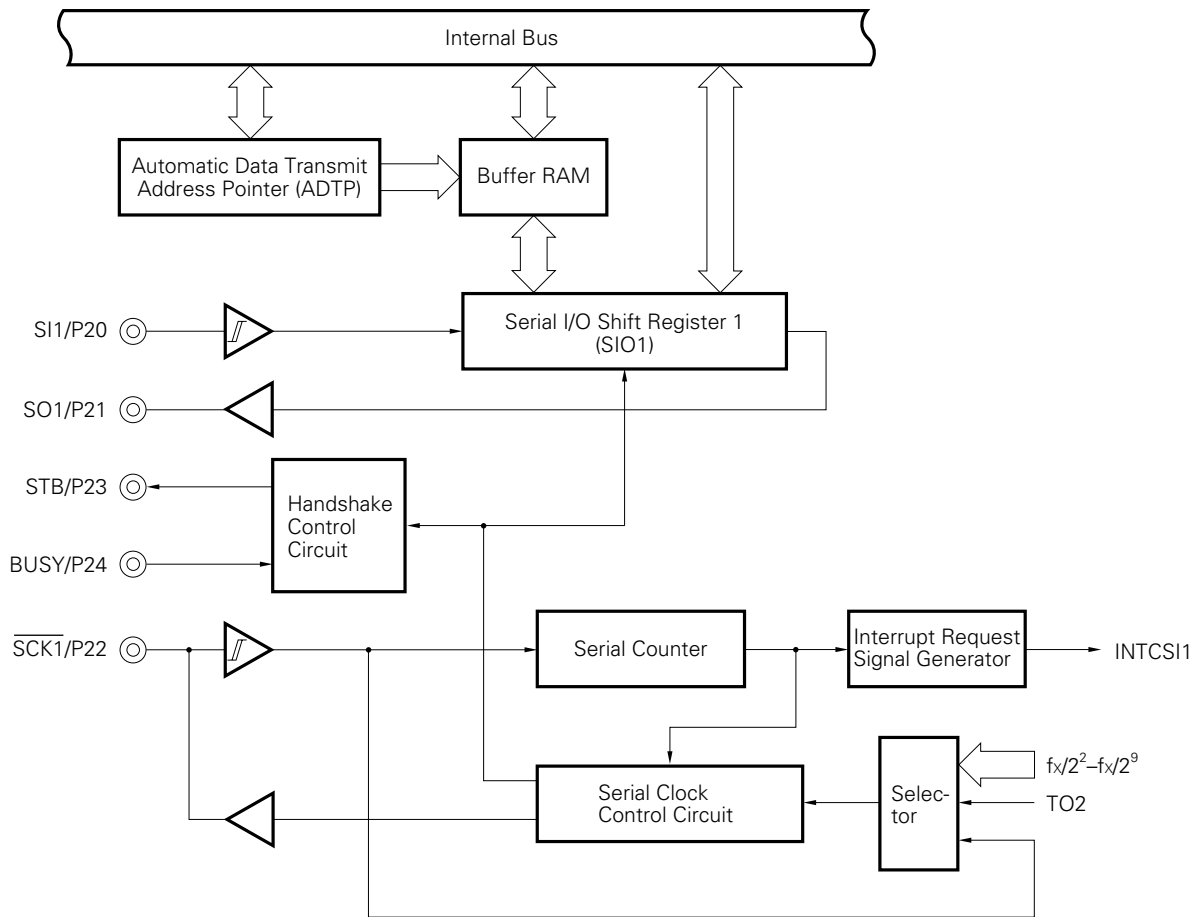


Fig. 5-10 Serial Interface Channel 1 Block Diagram



6. INTERRUPT FUNCTIONS AND TEST FUNCTIONS

6.1 INTERRUPT FUNCTIONS

The following 3 types of 14 interrupt functions are set:

- Non-maskable interrupt : 1
- Maskable interrupt : 12
- Software interrupt : 1

Table 6-1 Interrupt Sources

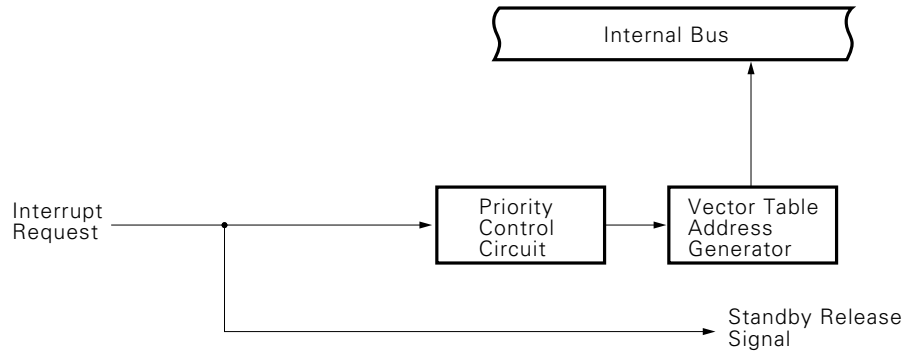
Interrupt Type	Default Priority ^{Note 1}	Interrupt Source		Internal/External	Vector Table Address	Basic Configuration Type ^{Note 2}		
		Name	Trigger					
Non-maskable	—	INTWDT	Watchdog timer overflow (non-maskable interrupt selection)	Internal	0004H	A		
Maskable	0	INTWDT	Watchdog timer overflow (interval timer selection)			External	0006H 0008H 000AH 000CH	B
	1	INTP0	Pin input edge detection	Internal	000EH 0010H 0012H 0014H 0016H 0018H 001AH			C
	2	INTP1						B
	3	INTP2						
	4	INTP3						
	5	INTCS10	End of serial interface channel 0 transfer	Internal	000EH 0010H 0012H 0014H 0016H 0018H 001AH	B		
	6	INTCS11	End of serial interface channel 1 transfer					
	7	INTTM3	Reference time interval signal from watch timer					
	8	INTTM0	16-bit timer/event counter match signal generation					
	9	INTTM1	8-bit timer/event counter 1 match signal generation					
	10	INTTM2	8-bit timer/event counter 2 match signal generation					
	11	INTAD	End of A/D converter conversion					
Software	—	BRK	BRK instruction execution	Internal	003EH	E		

Notes 1. Default priority is the priority when multiple maskable interrupts are generated at the same time. 0 is first, 11 is last.

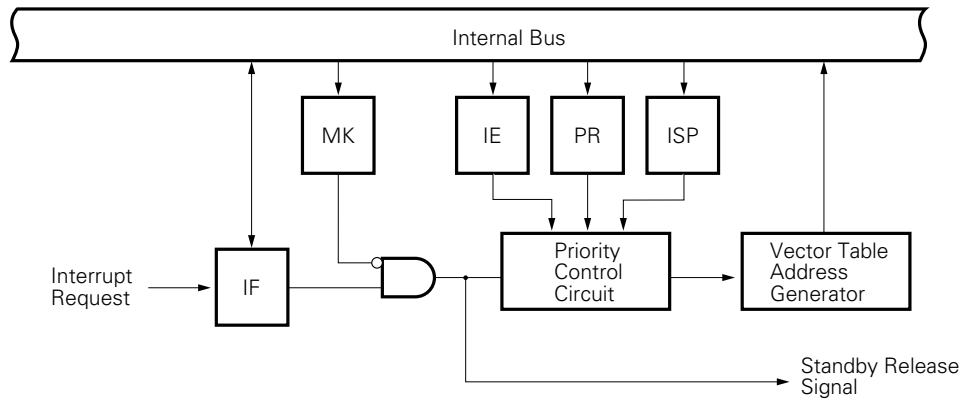
2. Basic configuration types A to E correspond to A to E on the following pages.

Fig. 6-1 Interrupt Function Basic Configuration (1/2)

(A) Internal non-maskable interrupt



(B) Internal maskable interrupt



(C) External maskable interrupt (INTP0)

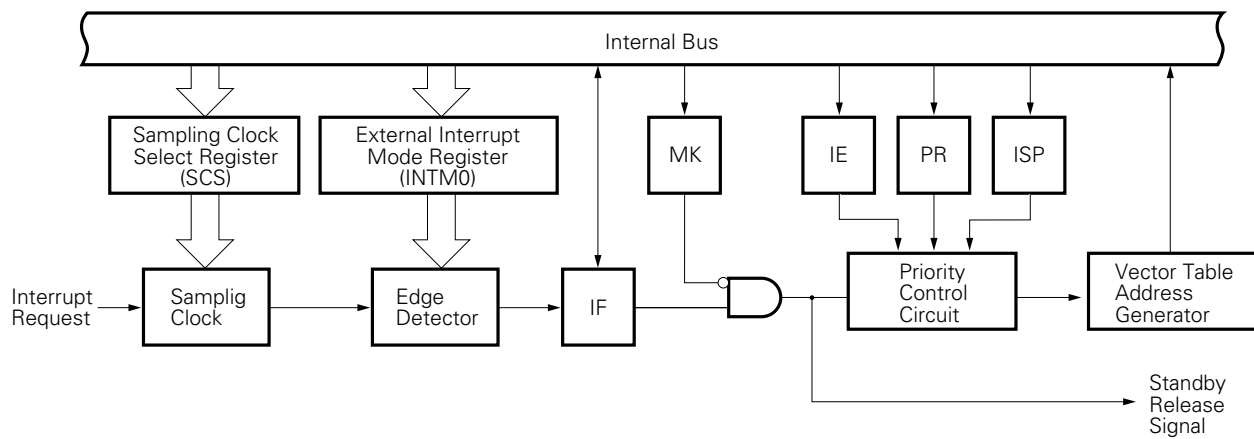
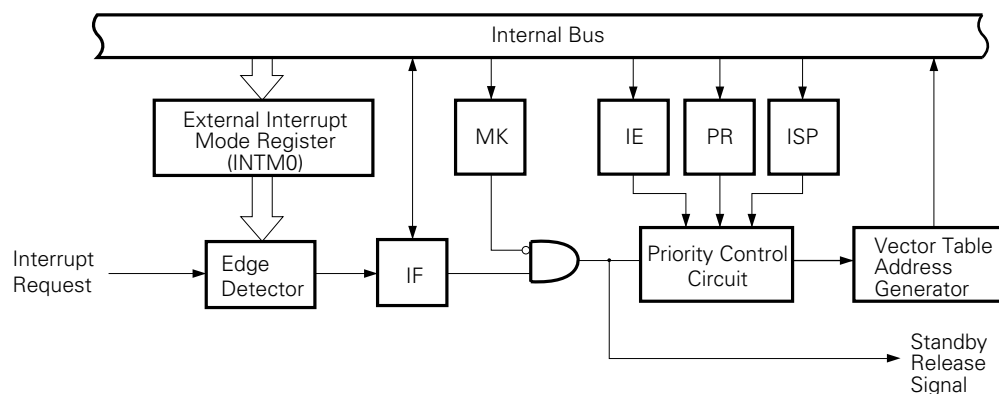
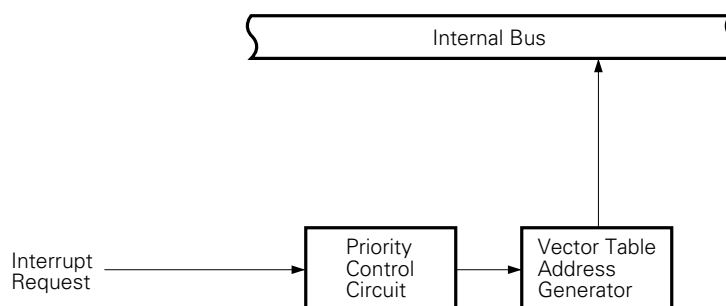


Fig. 6-1 Interrupt Function Basic Configuration (2/2)

(D) External maskable interrupt (except INTP0)



(E) Software interrupt



- Remarks**
1. IF : Interrupt request flag
 2. IE : Interrupt enable flag
 3. ISP : In-service priority flag
 4. MK : Interrupt mask flag
 5. PR : Priority specification flag

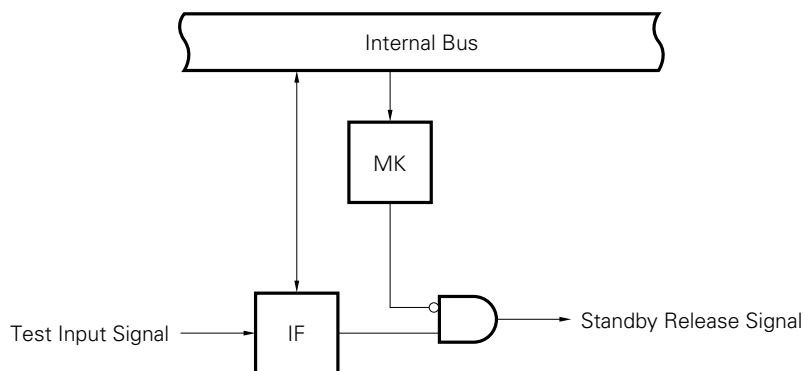
6.2 TEST FUNCTIONS

The 2 test functions are set as shown in Table 6-2.

Table 6-2 Test Source list

Test Source		Internal/External
Name	Trigger	
INTWT	Watch timer overflow	Internal
INTPT4	Port 4 falling edge detection	External

Fig. 6-2 Test Function Basic Configuration



- Remarks**
1. IF : Test Input Flag
 2. MK : Test Mask Flag

7. EXTERNAL DEVICE EXPANSION FUNCTIONS

The external device expansion functions connect external devices to areas other than the internal ROM, RAM and SFR.

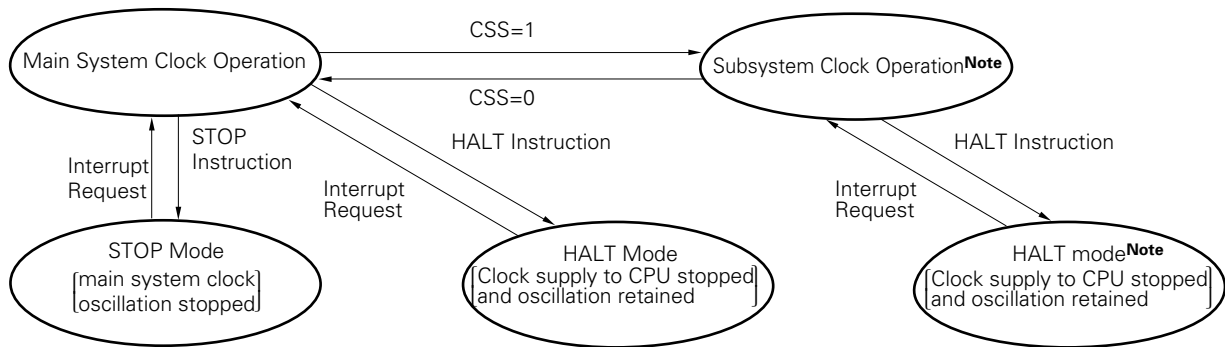
External devices connection uses ports 4 to 6.

8. STANDBY FUNCTION

There are the following two standby functions to reduce the system power consumption.

- o HALT mode : In this mode, the CPU operation clock is stopped. The average consumption current can be reduced by intermittent operation in combination with the normal operation.
- o STOP mode : In this mode, the main system clock oscillator is stopped. The power consumption are greatly reduced to subsystem clock only by stopping the whole main system, clock operations.

Figure 8-1 Standby Function



Note Stopping the main system clock enables the consumption current to be reduced. If the CPU is operated by the subsystem clock, the main system clock should be stopped by the MCC set. STOP instruction is not available.

Caution If the CPU is operated by the subsystem clock when the main system clock is stopped, reswitching to the main system should be performed after the stable oscillation time has been obtained by the program.

9. RESET FUNCTION

There are the following two reset methods.

- External reset by \overline{RESET} pin
- Internal reset by watchdog time runaway time detection

10. INSTRUCTION SET

(1) 8-Bit Instructions

MOV, XCH, ADD, ADDC, SUB, SUBC, AND, OR, XOR, CMP, MULU, DIVUW, INC, DEC, ROR, ROL, RORC, ROLC, ROR4, ROL4, PUSH, POP, DBNZ

Second Operand First Operand	#byte	A	rNote	sfr	saddr	!addr16	PSW	[DE]	[HL]	[HL + byte] [HL + B] [HL + C]	\$addr16	1	None
A	ADD ADDC SUB SUBC AND OR XOR CMP		MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP	MOV XCH	MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP	MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP	MOV	MOV XCH	MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP	MOV XCH ADD ADDC SUB SUBC AND OR XOR CMP		ROR ROL RORC ROLC	
r	MOV	MOV ADD ADDC SUB SUBC AND OR XOR CMP											INC DEC
r1											DBNZ		
sfr	MOV	MOV											
saddr	MOV ADD ADDC SUB SUBC AND OR XOR CMP	MOV									DBNZ		INC DEC
!addr16		MOV											
PSW	MOV	MOV											PUSH POP
[DE]		MOV											
[HL]		MOV											ROR4 ROL4
[HL + byte] [HL + B] [HL + C]		MOV											
X													MULU
C													DIVUW

Note Except r = A

(2) 16-Bit Instructions

MOVW, XCHW, ADDW, SUBW, CMPW, PUSH, POP, INCW, DECW

Second Operand First Operand	#word	AX	rp ^{Note}	sfrp	saddrp	!addr16	SP	None
AX	ADDW SUBW CMPW		MOVW XCHW	MOVW	MOVW	MOVW	MOVW	
rp	MOVW	MOVW*						INCW, DECW PUSH, POP
sfrp	MOVW	MOVW						
saddrp	MOVW	MOVW						
!addrp16		MOVW						
SP	MOVW	MOVW						

Note Only in the case of rp = BC, DE, HL

(3) Bit Manipulation Instructions

MOV1, AND1, OR1, XOR1, SET1, CLR1, NOT1, BT, BF, BTCLR

Second Operand First Operand	A.bit	sfr.bit	saddr.bit	PSW.bit	[HL].bit	CY	\$addr16	None
A.bit						MOV1	BT BF BTCLR	SET1 CLR1
sfr.bit						MOV1	BT BF BTCLR	SET1 CLR1
saddr.bit						MOV1	BT BF BTCLR	SET1 CLR1
PSW.bit						MOV1	BT BF BTCLR	SET1 CLR1
[HL].bit						MOV1	BT BF BTCLR	SET1 CLR1
CY	MOV1 AND1 OR1 XOR1	MOV1 AND1 OR1 XOR1	MOV1 AND1 OR1 XOR1	MOV1 AND1 OR1 XOR1	MOV1 AND1 OR1 XOR1			SET1 CLR1 NOT1

(4) Call Instruction/Branch Instructions

CALL, CALLF, CALLT, BR, BC, BNC, BZ, BNZ, BT, BF, BTCLR, DBNZ

Second Operand First Operand	AX	!addr16	!addr11	[addr5]	\$addr16
Basic Instruction	BR	CALL, BR	CALLF	CALLT	BR, BC, BNC, BZ, BNZ
Compound Instruction					BT, BF, BTCLR, DBNZ

(5) Other Instructions

ADJBA, ADJBS, BRK, RET, RET1, RETB, SEL, NOP, EI, DI, HALT, STOP

11. ELECTRICAL SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

PARAMETER	SYMBOL	TEST CONDITIONS		RATING	UNIT		
Supply voltage	V _{DD}			-0.3 to + 7.0	V		
	AV _{DD}			-0.3 to V _{DD} + 0.3	V		
	AV _{REF}			-0.3 to V _{DD} + 0.3	V		
	AV _{SS}			-0.3 to + 0.3	V		
Input voltage	V _{I1}	P00 to P04, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P64 to P67, X1, X2, XT2		-0.3 to V _{DD} + 0.3	V		
	V _{I2}	P60 to P63	Open-drain	-0.3 to +16	V		
Output voltage	V _O			-0.3 to V _{DD} + 0.3	V		
Analog input voltage	V _{AN}	P10 to P17	Analog input pin	AV _{SS} -0.3 to AV _{REF} + 0.3	V		
Output current high	I _{OH}	1 pin		-10	mA		
		P10 to P17, P20 to P27, P30 to P37 total		-15	mA		
		P01 to P03, P40 to P47, P50 to P57, P60 to P67 total		-15	mA		
Output current low	I _{OL} Note	1 pin	Peak value	30	mA		
			Effective value	15	mA		
		P40 to P47, P50 to P55 total	Peak value	100	mA		
			Effective value	70	mA		
		P01 to P03, P56, P57, P60 to P67 total	Peak value	100	mA		
			Effective value	70	mA		
		P01 to P03, P64 to P67 total	Peak value	50	mA		
			Effective value	20	mA		
		P10 to P17, P20 to P27, P30 to P37 total	Peak value	50	mA		
			Effective value	20	mA		
		Operating temperature	T _{opt}			-40 to +85	°C
		Storage temperature	T _{stg}			-65 to +150	°C

Note Effective value should be calculated as follows: [Effective value] = [Peak value] × √duty

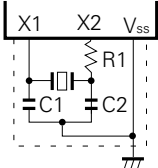
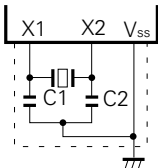
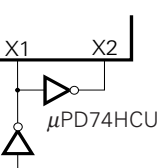
Caution Absolute maximum ratings are rated values beyond which some physical damages may be caused to the product; if any of the parameters in the table above exceeds its rated value even for a moment, the quality of the product may deteriorate. Be sure to use the product within the rated values.

CAPACITANCE (Ta = 25 °C, VDD = VSS = 0 V)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Input capacitance	C _{IN}	f = 1M Hz Unmeasured pins returned to 0 V.				15	pF
I/O capacitance	C _{IO}	f = 1 MHz Unmeasured pins returned to 0 V.	P01 to P03, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P64 to P67			15	pF
			P60 to P63			20	pF

Remark Unless otherwise specified, characteristics of the dual-function pins are equivalent to those of the port pins.

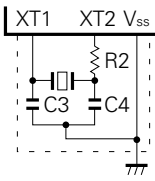
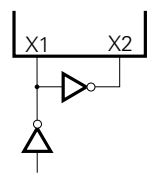
MAIN SYSTEM CLOCK OSCILLATION CIRCUIT CHARACTERISTICS (Ta = -40 to +85 °C, VDD = 2.7 to 6.0 V)

RESONATOR	RECOMMENDED CIRCUIT	PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Ceramic resonator		Oscillator frequency (f _x) ^{Note1}	V _{DD} = Oscillator voltage range	1		10	MHz
		Oscillation stabilization time ^{Note2}	After V _{DD} reaches oscillator voltage range MIN.			4	ms
Crystal resonator		Oscillator frequency (f _x) ^{Note1}		1	8.38	10	MHz
		Oscillation stabilization time ^{Note2}	V _{DD} = 4.5 to 6.0 V			10 30	ms
External clock		X1 input frequency (f _x) ^{Note1}		1.0		10.0	MHz
		X1 input high/low level width (t _{xH} , t _{xL})		42.5		500	ns

- Notes**
1. Indicates only oscillation circuit characteristics.
Refer to “AC Characteristics” for instruction execution time.
 2. Time required to stabilize oscillation after reset or STOP mode release.

- Cautions**
1. When using the main system clock oscillator, wiring in the area enclosed with the dotted line should be carried out as follows to avoid an adverse effect from wiring capacitance.
 - Wiring should be as short as possible.
 - Wiring should not cross other signal lines.
 - Wiring should not be placed close to a varying high current.
 - The potential of the oscillator capacitor ground should be the same as V_{SS}.
 - Do not ground it to the ground pattern in which a high current flows.
 - Do not fetch a signal from the oscillator.
 2. If the main system clock oscillation circuit is operated by the subsystem clock when the main system clock is stopped, reswitching to the main system clock should be performed after the stable oscillation time has been obtained by the program.

SUBSYSTEM CLOCK OSCILLATION CIRCUIT CHARACTERISTICS (Ta = -40 to +85 °C, VDD = 2.7 to 6.0 V)

RESONATOR	RECOMMENDED CIRCUIT	PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Crystal resonator		Oscillator frequency (f _{XT1}) Note 1		32	32.768	35	kHz
		Oscillation stabilization time Note 2	V _{DD} = 4.5 to 6.0 V		1.2	2	s
External clock		XT1 input frequency (f _{XT1}) Note 1		32		100	kHz
		XT1 input high/low level width (t _{XTH} , t _{XTL})		5		15	μs

- Notes**
1. Indicates only oscillation circuit characteristics.
Refer to “AC Characteristics” for instruction execution time.
 2. Time required to stabilize oscillation after V_{DD} has reached the minimum oscillation voltage range.

- Cautions**
1. When using the subsystem clock oscillator, wiring in the area enclosed with the dotted line should be carried out as follows to avoid an adverse effect from wiring capacitance.
 - Wiring should be as short as possible.
 - Wiring should not cross other signal lines.
 - Wiring should not be placed close to a varying high current.
 - The potential of the oscillator capacitor ground should be the same as V_{SS}.
 - Do not ground it to the ground pattern in which a high current flows.
 - Do not fetch a signal from the oscillator.
 2. The subsystem clock oscillation circuit is designed as a low amplification circuit to provide low consumption current, causing misoperation to noise more frequently than the main system clock. Special care should therefore be taken to wiring method when the subsystem clock is used.

RECOMMENDED OSCILLATION CIRCUIT CONSTANT

MAIN SYSTEM CLOCK: CERAMIC RESONATOR (Ta = -40 to +85 °C)

In the case of μPD78011BY and μPD78012BY

MANU-FACTURER	PRODUCT NAME	FREQUENCY (MHz)	RECOMMENDED CIRCUIT CONSTANT			OSCILLATOR VOLTAGE RANGE	
			C1 (pF)	C2 (pF)	R1 (kΩ)	MIN. (V)	MAX. (V)
Murata Mfg. Co., Ltd.	CSB1000J	1.00	100	100	6.8	2.9	6.0
	CSBxxxxJ	1.01 to 1.25	100	100	4.7	2.7	6.0
	CSAx. xxxMK	1.26 to 1.79	100	100	0	2.7	6.0
	CSAx. xxMG	1.80 to 2.44	100	100	0	2.7	6.0
	CSTx. xxMG		Built-in	Built-in	0	2.7	6.0
	CSAx. xxMG	2.45 to 4.18	30	30	0	2.7	6.0
	CSTx. xxMGW		Built-in	Built-in	0	2.7	6.0
	CSAx. xxMG	4.19 to 6.00	30	30	0	2.7	6.0
	CSTx. xxMGW		Built-in	Built-in	0	2.7	6.0
	CSAx. xxMT	6.01 to 10.0	30	30	0	2.9	6.0
	CSTx. xxMTW		Built-in	Built-in	0	2.9	6.0
Kyocera	KBR-4. 19MWS	4.19	-	-	-	2.7	6.0
	KBR-4. 19MKS		-	-	-	2.7	6.0
	KBR-4. 19MSA	4.19	33	33	-	2.7	6.0
	PBRC4. 19A		33	33	-	2.8	6.0
	KBR-10. 0M	10.0	33	33	-	2.8	6.0
	KBR-1000F	1.00	100	100	2.2	2.7	6.0
	KBR-1000Y						

In the case of μPD78013Y and μPD78014Y

MANUFACTURER	PRODUCT NAME	FREQUENCY (MHz)	RECOMMENDED CIRCUIT CONSTANT			OSCILLATOR VOLTAGE RANGE	
			C1 (pF)	C2 (pF)	R1 (kΩ)	MIN. (V)	MAX. (V)
Murata Mfg. Co., Ltd.	CSB1000J	1.00	100	100	6.8	2.7	6.0
	CSBxxxxJ	1.01 to 1.25	100	100	4.7	2.7	6.0
	CSAx. xxxMK	1.26 to 1.79	100	100	0	2.7	6.0
	CSAx. xxMG	1.80 to 2.44	100	100	0	2.7	6.0
	CSTx. xxMG		Built-in	Built-in	0	2.7	6.0
	CSAx. xxMG	2.45 to 4.18	30	30	0	2.7	6.0
	CSTx. xxMGW		Built-in	Built-in	0	2.7	6.0
	CSAx. xxMG	4.19 to 6.00	30	30	0	2.7	6.0
	CSTx. xxMGW		Built-in	Built-in	0	2.7	6.0
	CSAx. xxMT	6.01 to 10.0	30	30	0	2.7	6.0
	CSTx. xxMTW		Built-in	Built-in	0	2.7	6.0

Remarks xxxx, x. xxx, x. xx indicates frequency.

SUBSYSTEM CLOCK: CRYSTAL RESONATOR (Ta = -40 to + 60 °C)

In the case of μPD78011BY and μPD78012BY

MANUFACTURER	PRODUCT NAME	FREQUENCY (kHz)	RECOMMENDED CIRCUIT CONSTANT			OSCILLATOR VOLTAGE RANGE	
			C3 (pF)	C4 (pF)	R2 (kΩ)	MIN. (V)	MAX. (V)
Daishinku	DT-38 (1TA632E00, load capacitance 6.3 pF)	32.768	8	8	100	2.7	6.0

In the case of μPD78013Y and μPD78014Y

MANUFACTURER	PRODUCT NAME	FREQUENCY (kHz)	RECOMMENDED CIRCUIT CONSTANT			OSCILLATOR VOLTAGE RANGE	
			C3 (pF)	C4 (pF)	R2 (kΩ)	MIN. (V)	MAX. (V)
Daishinku	DT-38 (1TA632E00, load capacitance 6.3 pF)	32.768	12	12	100	2.7	6.0

DC CHARACTERISTICS (Ta = -40 to +85 °C, VDD = 2.7 to 6.0 V)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Input voltage high	V _{IH1}	P10 to P17, P21, P23, P30 to P32, P35 to P37, P40 to P47, P50 to P57, P64 to P67		0.7 V _{DD}		V _{DD}	V	
	V _{IH2}	P00 to P03, P20, P22, P24 to P27, P33, P34, RESET		0.8 V _{DD}		V _{DD}	V	
	V _{IH3}	P60 to P63	Open-drain	0.7 V _{DD}		15	V	
	V _{IH4}	X1, X2		V _{DD} -0.5		V _{DD}	V	
	V _{IH5}	XT1/P04, XT2	V _{DD} = 4.5 to 6.0 V	V _{DD} -0.5		V _{DD}	V	
V _{DD} -0.3					V _{DD}	V		
Input voltage low	V _{IL1}	P10 to P17, P21, P23, P30 to P32, P35 to P37, P40 to P47, P50 to P57, P64 to P67		0		0.3 V _{DD}	V	
	V _{IL2}	P00 to P03, P20, P22, P24 to P27, P33, P34, RESET		0		0.2 V _{DD}	V	
	V _{IL3}	P60 to P63	V _{DD} = 4.5 to 6.0 V	0		0.3 V _{DD}	V	
				0		0.2 V _{DD}	V	
	V _{IL4}	X1, X2		0		0.4	V	
V _{IL5}	XT1/P04, XT2	V _{DD} = 4.5 to 6.0 V	0		0.4	V		
			0		0.3	V		
Output voltage high	V _{OH1}	V _{DD} = 4.5 to 6.0 V, I _{OH} = -1 mA		V _{DD} -1.0			V	
		I _{OH} = -100 μA		V _{DD} -0.5			V	
Output voltage low	V _{OL1}	P50 to P57, P60 to P63	V _{DD} = 4.5 to 6.0 V, I _{OL} = 15 mA		0.4	2.0	V	
		P01 to P03, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P64 to P67	V _{DD} = 4.5 to 6.0 V, I _{OL} = 1.6 mA			0.4	V	
	V _{OL2}	SB0, SB1, SCK0	V _{DD} = 4.5 to 6.0 V, open-drain pulled-up (R = 1 KΩ)			0.2 V _{DD}	V	
	V _{OL3}	I _{OL} = 400 μA				0.5	V	
Input leakage current high	I _{LIH1}	V _{IN} = V _{DD}	P00 to P03, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P64 to P67, RESET					
			X1, X2, XT1/P04, XT2			20	μA	
	I _{LIH3}	V _{IN} = 15 V	P60 to P63			80	μA	
Input leakage current low	I _{LIL1}	V _{IN} = 0 V	P00 to P03, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P64 to P67, RESET			-3	μA	
			X1, X2, XT1/P04, XT2			-20	μA	
	I _{LIL3}		P60 to P63	Note 1			-200	μA
			Other than above				-3Note 2	μA

- Notes**
1. When memory expansion mode is used by the memory expansion mode register (MM) with no on-chip pull-up resistor by mask option.
 2. Non-use of pull-up resistor (specified by mask option) increases low-level input leakage current in -200 μA (MAX.) in either of the following cases:
 - ① When the low-level input is performed to the pin using the external device expansion function is used.
 - ② For 3-clock cycle when the port 6 (P6)/port mode register (PM6) read instruction execution is performed.

DC CHARACTERISTICS (Ta = -40 to +85 °C, VDD = 2.7 to 6.0 V)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Output leakage current high	I _{LOH1}	V _{OUT} = V _{DD}			3	μA	
Output leakage current low	I _{LOL}	V _{OUT} = 0 V			-3	μA	
Mask option pull-up resistor	R ₁	V _{IN} = 0 V, P60 to P63	20	40	90	kΩ	
Software pull-up resistor	R ₂	V _{IN} = 0 V, P01 to P03, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P64 to P67	4.5 V ≤ V _{DD} ≤ 6.0 V	15	40	90	kΩ
		2.7 V ≤ V _{DD} ≤ 4.5 V	20		500	kΩ	
Power supply current ^{Note 3}	I _{DD1}	8.38 MHz, Crystal oscillation operating mode	V _{DD} = 5.0 V ± 10 % ^{Note 1}		7.5	22.5	mA
			V _{DD} = 3.0 V ± 10 % ^{Note 2}		0.8	2.4	mA
	I _{DD2}	8.38 MHz, Crystal oscillation HALT mode	V _{DD} = 5.0 V ± 10 %		1.4	4.2	mA
			V _{DD} = 3.0 V ± 10 %		550	1650	μA
	I _{DD3}	32,768 kHz, Crystal oscillation operating mode	V _{DD} = 5.0 V ± 10 %		60	120	μA
			V _{DD} = 3.0 V ± 10 %		35	70	μA
	I _{DD4}	32,768 kHz, Crystal oscillation HALT mode	V _{DD} = 5.0 V ± 10 %		25	50	μA
			V _{DD} = 3.0 V ± 10 %		5	10	μA
	I _{DD5}	XT1 = 0 V STOP mode When feedback resistor is connected	V _{DD} = 5.0 V ± 10 %		1	20	μA
			V _{DD} = 3.0 V ± 10 %		0.5	10	μA
	I _{DD6}	XT1 = 0 V STOP mode When feedback resistor is disconnected	V _{DD} = 5.0 V ± 10 %		0.1	20	μA
			V _{DD} = 3.0 V ± 10 %		0.05	10	μA

- Notes**
1. Operating in high-speed mode (when set the processor clock control register to 00H)
 2. Operating in low-speed mode (when set the processor clock control register to 04H)
 3. AV_{REF} current and port current are excluded.

Remark Unless otherwise specified, characteristics of the dual-function pins are equivalent to those of the port pins.

AC CHARACTERISTICS

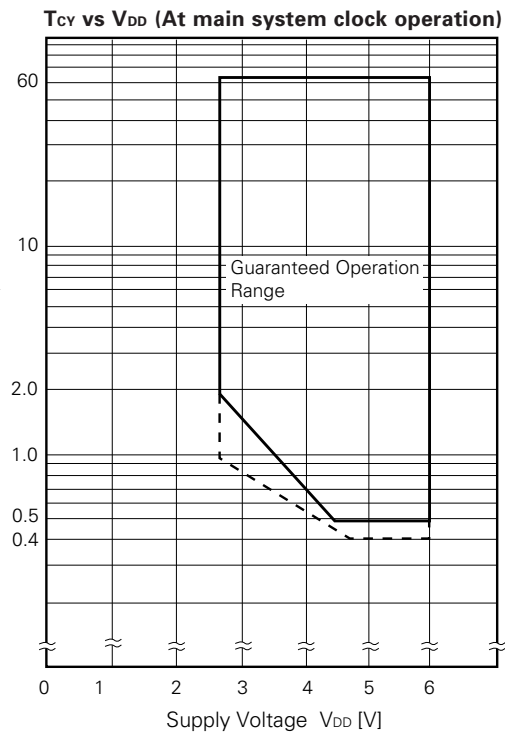
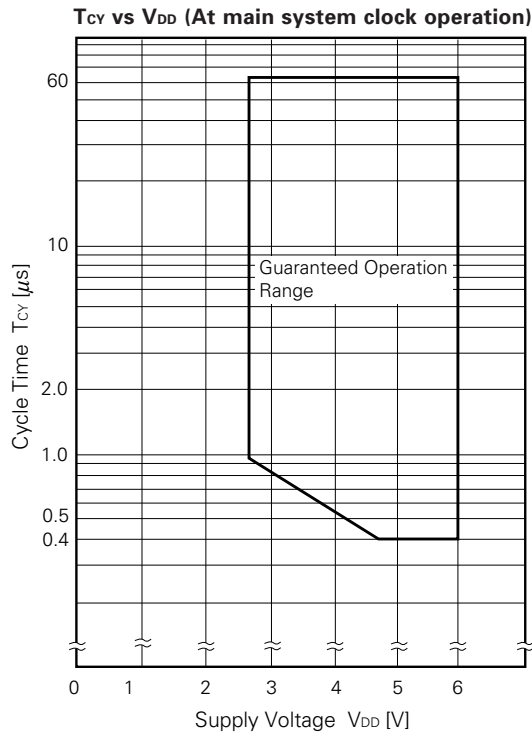
(1) Basic Operation (Ta = -40 to +85 °C, VDD = 2.7 to 6.0 V)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Cycle time (Min. instruction execution time)	T _{CY}	Operating on main system clock V _{DD} = 4.5 to 6.0 V	0.4		64	μs
			0.96		64	μs
		Operating on subsystem clock	40	122	125	μs
Tl input frequency	f _{tl}	V _{DD} = 4.5 to 6.0 V	0		4	MHz
			0		275	kHz
Tl input high/low-level width	t _{TIH} t _{TIL}	V _{DD} = 4.5 to 6.0 V	100			ns
			1.8			μs
Interrupt input high/low-level width	t _{INTH} t _{INTL}	INTP0	8/f _{sam} Note			μs
		INTP1 to INTP3	10			μs
		KR0 to KR7	10			μs
RESET low level width	t _{RST}		10			μs

Note In combination with bits 0 (SCS0) and 1 (SCS1) of sampling clock select register, selection of f_{sam} is possible between f_x/2^{N+1}, f_x/64 and f_x/128 (when N = 0 to 4).

In the case of μPD78011BY, μPD78012BY, μPD78013Y and μPD78014Y

In the case of μPD78P014Y



Caution The guaranteed operation range differs between μPD78011BY, μPD78012BY, μPD78013Y, μPD78014Y and μPD78P014Y.

Remarks - - - - - indicates Ta = -40 to +40 °C
 _____ indicates Ta = -40 to +85 °C

(2) Read/Write Operation (Ta = -40 to +85 °C, VDD = 2.7 to 6.0 V)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	MAX.	UNIT
ASTB high-level width	tASTH		0.5tcy		ns
Address setup time	tADS		0.5tcy-30		ns
Address hold time	tADH	Load resistor ≥ 5 kΩ	10		ns
Data input time from address	tADD1			(2+2n)tcy-50	ns
	tADD2		5	(3+2n)tcy-100	ns
Data input time from RD↓	trDD1			(1+2n)tcy-25	ns
	trDD2			(2.5+2n)tcy-100	ns
Read data hold time	trDH		0		ns
RD low-level width	trDL1		(1.5+2n)tcy-20		ns
	trDL2		(2.5+2n)tcy-20		ns
WAIT↓ input time from RD↓	trDWT1			0.5tcy	ns
	trDWT2			1.5tcy	ns
WAIT↓ input time from WR↓	tWRWT			0.5tcy	ns
WAIT low-level width	tWTL		(0.5+2n)tcy + 10	(2+2n)tcy	ns
Write data setup time	tWDS		100		ns
Write data hold time	tWDH		5		ns
WR low-level width	tWRL1		(2.5+2n)tcy -20		ns
RD↓ delay time from ASTB↓	tASTRD		0.5tcy-30		ns
WR↓ delay time from ASTB↓	tASTWR		1.5tcy -30		ns
ASTB↑ delay time from RD↑ in external fetch	trDAST		tcy-10	tcy+40	ns
Address hold time from RD↑ in external fetch	trDADH		tcy	tcy+50	ns
Write data output time from RD↑	trDWD		10		ns
WR↓ delay time from write data	tWDWR	VDD = 4.5 to 6.0 V	0.5tcy-120	0.5tcy	ns
			0.5tcy-170	0.5tcy	ns
Address hold time from WR↑	tWRADH	VDD = 4.5 to 6.0 V	tcy	tcy+60	ns
			tcy	tcy+100	ns
RD↑ delay time from WAIT↑	tWTRD		0.5tcy	2.5tcy+80	ns
WR↑ delay time from WAIT↑	tWTWR		0.5tcy	2.5tcy+80	ns

- Remarks**
1. tcy = Tcy/4
 2. n indicates number of waits.
 3. CL = 100 pF (CL indicates load capacitance of P40/AD0 to P47/AD7, P50/A8 to P57/A15, P64/RD, P65/WR, P66/WAIT, P67/ASTB pins)

(3) Serial Interface (Ta = -40 to +85 °C, VDD = 2.7 to 6.0 V)

(a) 3-wire serial I/O mode ($\overline{\text{SCK}}$... Internal clock output)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
SCK cycle time	t _{KCY1}	V _{DD} = 4.5 to 6.0 V		800			ns
				3200			ns
$\overline{\text{SCK}}$ high/low-level width	t _{KH1}	V _{DD} = 4.5 to 6.0 V		t _{KCY1} /2-50			ns
	t _{KL1}			t _{KCY1} /2-150			ns
SI setup time (to $\overline{\text{SCK}}\uparrow$)	t _{SIK1}			100			ns
SI hold time (from $\overline{\text{SCK}}\uparrow$)	t _{SI1}			400			ns
SO output delay time from $\overline{\text{SCK}}\downarrow$	t _{KSO1}	C = 100 pF ^{Note}	V _{DD} = 4.5 to 6.0 V			300	ns
						1000	ns

Note C is the load capacitance of SO output line.

(b) 3-wire serial I/O mode ($\overline{\text{SCK}}$...External clock input)

In the case of serial interface channel 0

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
$\overline{\text{SCK}}$ cycle time	t_{KCY2}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		800			ns
				3200			ns
$\overline{\text{SCK}}$ high/low-level width	t_{KH2}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		400			ns
	t_{KL2}			1600			ns
SI setup time (to $\overline{\text{SCK}}\uparrow$)	t_{SIK2}			100			ns
SI hold time (from $\overline{\text{SCK}}\uparrow$)	t_{KSI2}			400			ns
SO output delay time from $\overline{\text{SCK}}\downarrow$	t_{KSO2}	$C = 100 \text{ pF}$ Note	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$			300	ns
						1000	ns
★ $\overline{\text{SCK}}$ rise/fall time	t_{r1} t_{f1}	When external device expansion function is used				160	ns
		When external device expansion function is not used	When 16-bit timer output function is used			700	ns
			When 16-bit timer output function is not used			1000	ns

Note C is the load capacitance of SO output line.

★ In the case of serial interface channel 1

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
$\overline{\text{SCK}}$ cycle time	t_{KCY2}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		800			ns
				3200			ns
$\overline{\text{SCK}}$ high/low-level width	t_{KH2}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		400			ns
	t_{KL2}			1600			ns
SI setup time (to $\overline{\text{SCK}}\uparrow$)	t_{SIK2}			100			ns
SI hold time (from $\overline{\text{SCK}}\uparrow$)	t_{KSI2}			400			ns
SO output delay time from $\overline{\text{SCK}}\downarrow$	t_{KSO2}	$C = 100 \text{ pF}$ Note	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$			300	ns
						1000	ns
$\overline{\text{SCK}}$ rise/fall time	t_{r1} t_{f1}	When external device expansion function is used				160	ns
		When external device expansion function is not used				1000	ns

Note C is the load capacitance of SO output line.

(c) SBI mode ($\overline{\text{SCK}}$...Internal clock output)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
$\overline{\text{SCK}}$ cycle time	t_{KCY3}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		800			ns
				3200			ns
$\overline{\text{SCK}}$ high/low-level width	t_{KH3}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		$t_{\text{KCY3}}/2-50$			ns
	t_{KL3}			$t_{\text{KCY3}}/2-150$			ns
$\overline{\text{SB0}}$, $\overline{\text{SB1}}$ setup time (to $\overline{\text{SCK}}\uparrow$)	t_{SIK3}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		100			ns
				300			ns
$\overline{\text{SB0}}$, $\overline{\text{SB1}}$ hold time (from $\overline{\text{SCK}}\uparrow$)	t_{KSI3}			$t_{\text{KCY3}}/2$			ns
$\overline{\text{SB0}}$, $\overline{\text{SB1}}$ output delay time from $\overline{\text{SCK}}\downarrow$	t_{KSO3}	$R = 1 \text{ k}\Omega$, $C = 100 \text{ pF}$ Note	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$	0		250	ns
				0		1000	ns
$\overline{\text{SB0}}$, $\overline{\text{SB1}}\downarrow$ from $\overline{\text{SCK}}\uparrow$	t_{KSB}			t_{KCY3}			ns
$\overline{\text{SCK}}\downarrow$ from $\overline{\text{SB0}}$, $\overline{\text{SB1}}\downarrow$	t_{SBK}			t_{KCY3}			ns
$\overline{\text{SB0}}$, $\overline{\text{SB1}}$ high-level width	t_{SBH}			t_{KCY3}			ns
$\overline{\text{SB0}}$, $\overline{\text{SB1}}$ low-level width	t_{SBL}			t_{KCY3}			ns

Note R and C are the load resistors and load capacitance of the $\overline{\text{SB0}}$ and $\overline{\text{SB1}}$ output line.

(d) SBI mode ($\overline{\text{SCK}}$...External clock input)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
$\overline{\text{SCK}}$ cycle time	t_{KCY4}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		800			ns
				3200			ns
$\overline{\text{SCK}}$ high/low-level width	t_{KH4}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		400			ns
	t_{KL4}			1600			ns
SB0, SB1 setup time (to $\overline{\text{SCK}}\uparrow$)	t_{SIK4}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		100			ns
				300			ns
SB0, SB1 hold time (from $\overline{\text{SCK}}\uparrow$)	t_{KSI4}			$t_{\text{KCY4}}/2$			ns
SB0, SB1 output delay time from $\overline{\text{SCK}}\downarrow$	t_{KSO4}	R = 1 kΩ, C = 100 pF ^{Note}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$	0		300	ns
				0		1000	ns
SB0, SB1 \downarrow from $\overline{\text{SCK}}\uparrow$	t_{KSB}			t_{KCY4}			ns
$\overline{\text{SCK}}\downarrow$ from SB0, SB1 \downarrow	t_{SBK}			t_{KCY4}			ns
SB0, SB1 high-level width	t_{SBH}			t_{KCY4}			ns
SB0, SB1 low-level width	t_{SBL}			t_{KCY4}			ns
★ $\overline{\text{SCK}}$ rise/fall time	t_{R2} t_{F2}	When external device expansion function is used				160	ns
		When external device expansion function is not used	When 16-bit timer output function is used			700	ns
			When 16-bit timer output function is not used			1000	ns

Note R and C are the load resistors and load capacitance of the SB0 and SB1 output line.

(e) 2-wire serial I/O mode (SCK... Internal clock output)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
SCK cycle time	t _{KCY5}	V _{DD} = 4.5 to 6.0 V		1600			ns
				3800			ns
SCK high-level width	t _{KH5}	R = 1 kΩ, C = 100 pF ^{Note}		t _{KCY5} /2-50			ns
SCK low-level width	t _{KL5}			t _{KCY5} /2-50			ns
SB0, SB1 setup time (to SCK↑)	t _{SIK5}			300			ns
SB0, SB1 hold time (from SCK↑)	t _{KSI5}			600			ns
SB0, SB1 output delay time from SCK↓	t _{KSO5}	R = 1 kΩ, C = 100 pF ^{Note}	V _{DD} = 4.5 to 6.0 V	0		250	ns
				0		1000	ns

Note R and C are the load resistors and load capacitance of the SCK0, SB0 and SB1 output line.

(f) 2-wire serial I/O mode (SCK... External clock input)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
SCK cycle time	t _{KCY6}	V _{DD} = 4.5 to 6.0 V		1600			ns
				3800			ns
SCK high-level width	t _{KH6}			650			ns
SCK low-level width	t _{KL6}			800			ns
SB0, SB1 setup time (to SCK↑)	t _{SIK6}			100			ns
SB0, SB1 hold time (from SCK↑)	t _{KSI6}			t _{KCY6} /2			ns
SB0, SB1 output delay time from SCK↓	t _{KSO6}	R = 1 kΩ, C = 100 pF ^{Note}	V _{DD} = 4.5 to 6.0 V	0		300	ns
				0		1000	ns
SCK rise/fall time	t _{R3} t _{F3}	When external device expansion function is used				160	ns
		When external device expansion function is not used	When 16-bit timer output function is used			700	ns
			When 16-bit timer output function is not used			1000	ns

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Note R and C are the load resistors and load capacitance of the SCK0, SB0 and SB1 output line.

(g) I²C bus interface

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
SCL input clock frequency	f _{SCL}		0		100	kHz
Pre-transmission bus release time	t _{BUF}		4.7			μs
Start condition hold time	t _{HDSTA}		4.0			μs
SCL low level time	t _{LOW}		4.7			μs
SCL high level time	t _{HIGH}		4.0			μs
Start condition setup time	t _{SUSTA}		4.7			μs
Data hold time	t _{HDDAT}	Data is held in SCL fall time.	0			μs
Data setup time	t _{SUDAT}	V _{DD} = 4.5 to 6.0 V	250			ns
			700			ns
SDA0, SDA1, and SCL signal rise time	t _{R4} Note 1	R = 2 kΩ, C = 100 pFNote 3			1000	ns
	t _{R4} Note 2	When external device expansion function is used			160	ns
		When external device expansion function is not used	When 16-bit timer output function is used		700	ns
			When 16-bit timer output function is not used		1000	ns
SDA0, SDA1, SCL signal fall time	t _{F4}	R = 2 kΩ, C = 100 pFNote 3			300	ns
Stop condition setup time	t _{SUSTO}		4.7			μs

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- Notes**
1. When the internal clock output is used as the serial clock
 2. When the external clock input is used as the serial clock
 3. R and C indicate load resistance and load capacitance of SCL, SDA0 and SDA1 output line, respectively.

(h) 3-wire serial I/O mode with automatic transmit/receive function ($\overline{\text{SCK}}$...Internal clock output)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
$\overline{\text{SCK}}$ cycle time	t_{KCY7}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		800			ns
				3200			ns
$\overline{\text{SCK}}$ high/low-level width	t_{KH7}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		$t_{\text{KCY7}}/2-50$			ns
	t_{KL7}			$t_{\text{KCY7}}/2-150$			ns
SI setup time (to $\overline{\text{SCK}}\uparrow$)	t_{SIK7}			100			ns
SI hold time (from $\overline{\text{SCK}}\uparrow$)	t_{KSI7}			400			ns
SO output delay time from $\overline{\text{SCK}}\downarrow$	t_{KS07}	C = 100 pF ^{Note}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$			300	ns
						1000	ns
$\text{STB}\uparrow$ from $\overline{\text{SCK}}\uparrow$	t_{SBD}			400		t_{KCY7}	ns
Strobe signal high-level width	t_{SBW}			$t_{\text{KCY7}}-30$		$t_{\text{KCY7}}+30$	ns
Busy signal setup time (to busy signal detection timing)	t_{BYS}			100			ns
Busy signal hold time (from busy signal detection timing)	t_{BYH}			100			ns
$\overline{\text{SCK}}\downarrow$ from busy inactive	t_{SPS}					$2t_{\text{KCY7}}$	ns

Note C is the load capacitance of the SO output line.

(i) 3-wire serial I/O mode with automatic transmit/receive function ($\overline{\text{SCK}}$...External clock input)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
$\overline{\text{SCK}}$ cycle time	t_{KCY8}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		800			ns
				3200			ns
$\overline{\text{SCK}}$ high/low-level width	t_{KH8}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$		400			ns
	t_{KL8}			1600			ns
SI setup time (to $\overline{\text{SCK}}\uparrow$)	t_{SIK8}			100			ns
SI hold time (from $\overline{\text{SCK}}\uparrow$)	t_{KSI8}			400			ns
SO output delay time from $\overline{\text{SCK}}\downarrow$	t_{KSO8}	C = 100 pF ^{Note}	$V_{\text{DD}} = 4.5 \text{ to } 6.0 \text{ V}$			300	ns
						1000	ns
$\overline{\text{SCK}}$ rise/fall time	t_{r5}	When external device expansion function is used				160	ns
	t_{f5}	When external device expansion function is not used				1000	ns

Note C is the load capacitance of the SO output line.

A/D Converter ($T_a = -40 \text{ to } +85 \text{ }^\circ\text{C}$, $AV_{\text{DD}} = V_{\text{DD}} = 2.7 \text{ to } 6.0 \text{ V}$, $AV_{\text{SS}} = V_{\text{SS}} = 0 \text{ V}$)

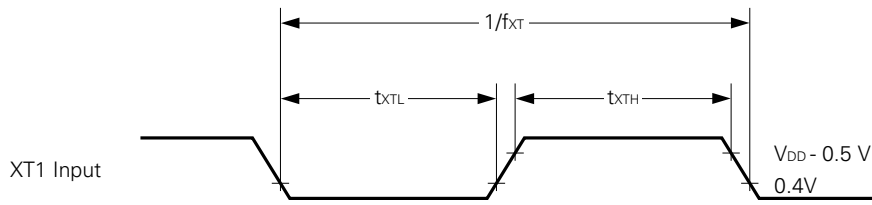
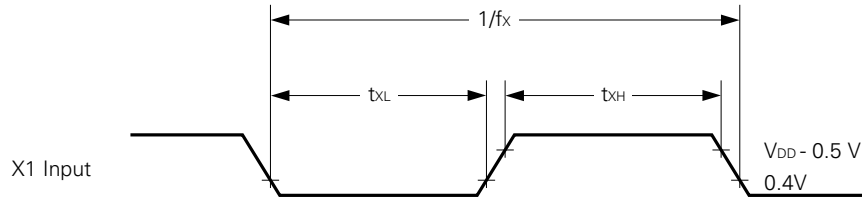
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Resolution			8	8	8	bit
Overall error ^{Note}					0.6	%
Conversion time	t_{CONV}		19.1		200	μs
Sampling time	t_{SAMP}		$24/f_x$			μs
Analog input voltage	V_{IAN}		AV_{SS}		AV_{REF}	V
Reference voltage	AV_{REF}		2.7		AV_{DD}	V
AV_{REF} current	AI_{REF}			0.5	1.5	mA

Note Quantization error ($\pm 1/2$ LSB) is not included. This is expressed in proportion to the full-scale value.

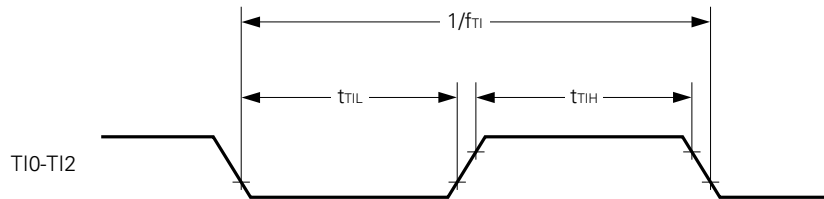
AC Timing Test Point (Excluding X1, XT1 Input)



Clock Timing

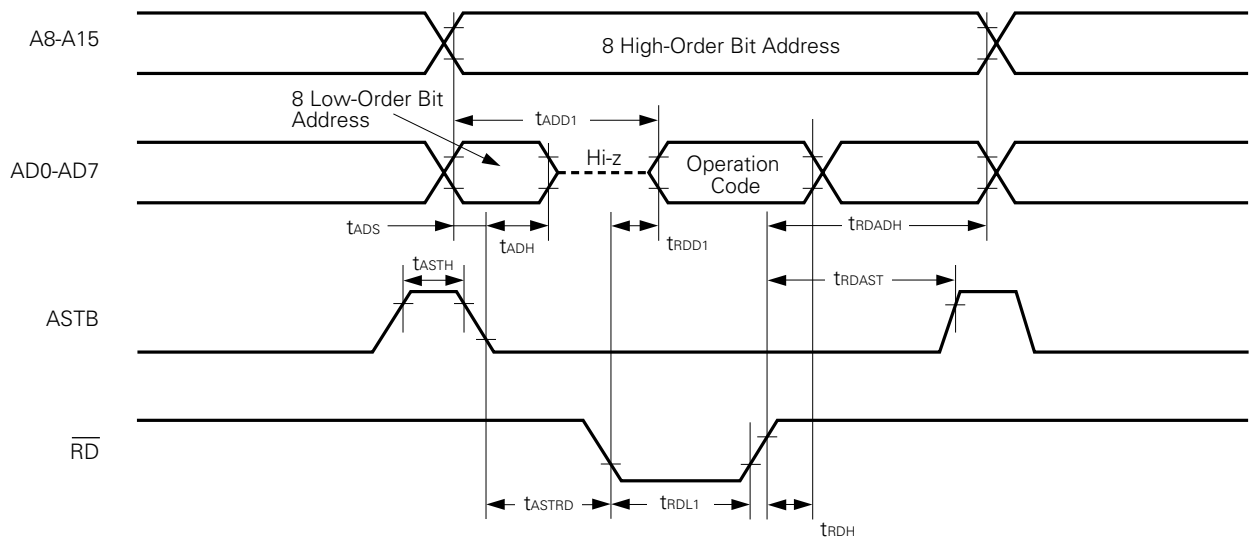


TI Timing

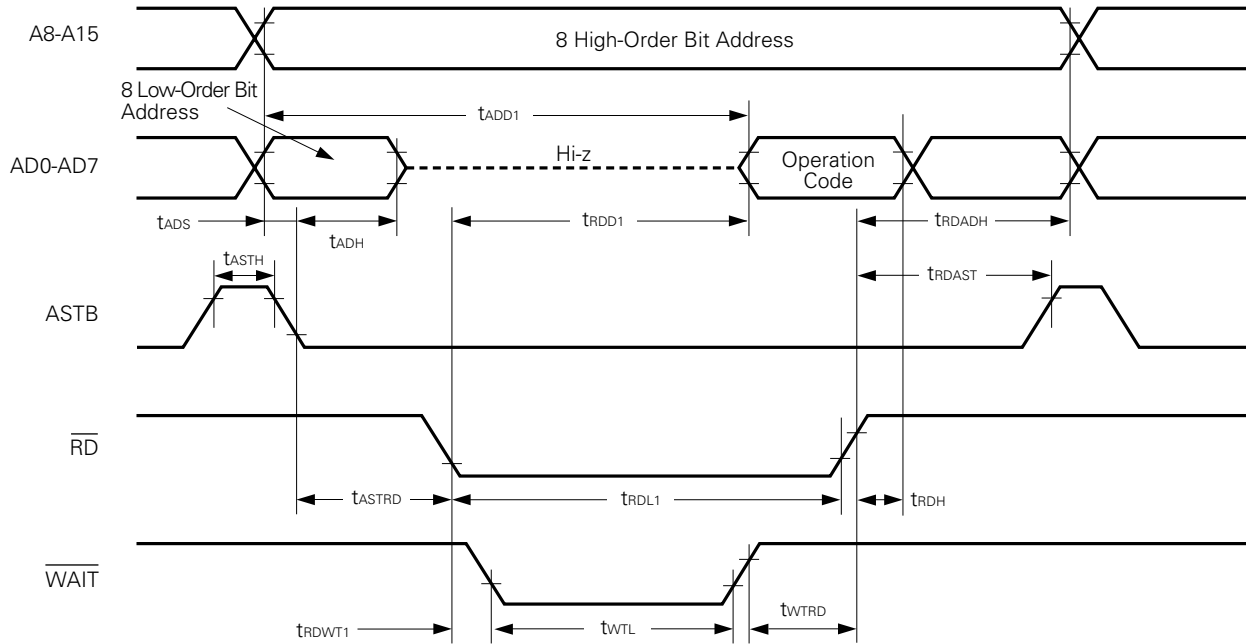


Read/Write Operation

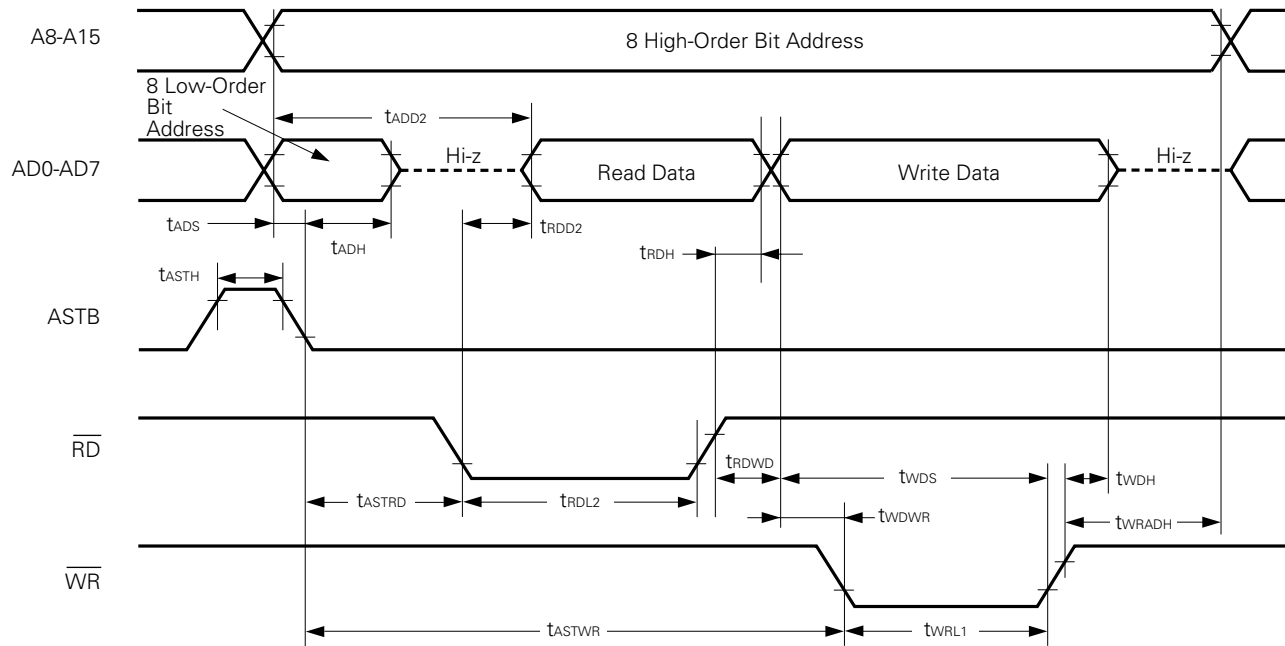
External fetch (no wait):



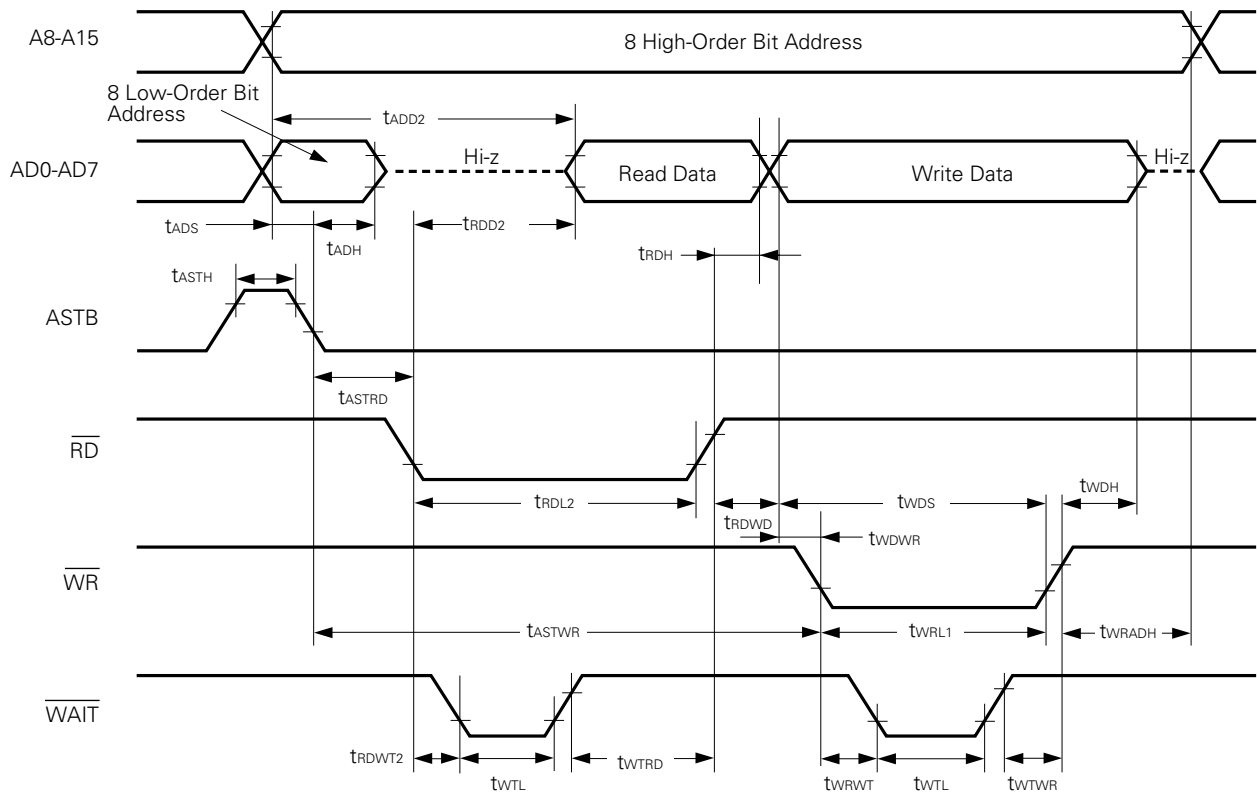
External fetch (wait insertion):



External data access (no wait):

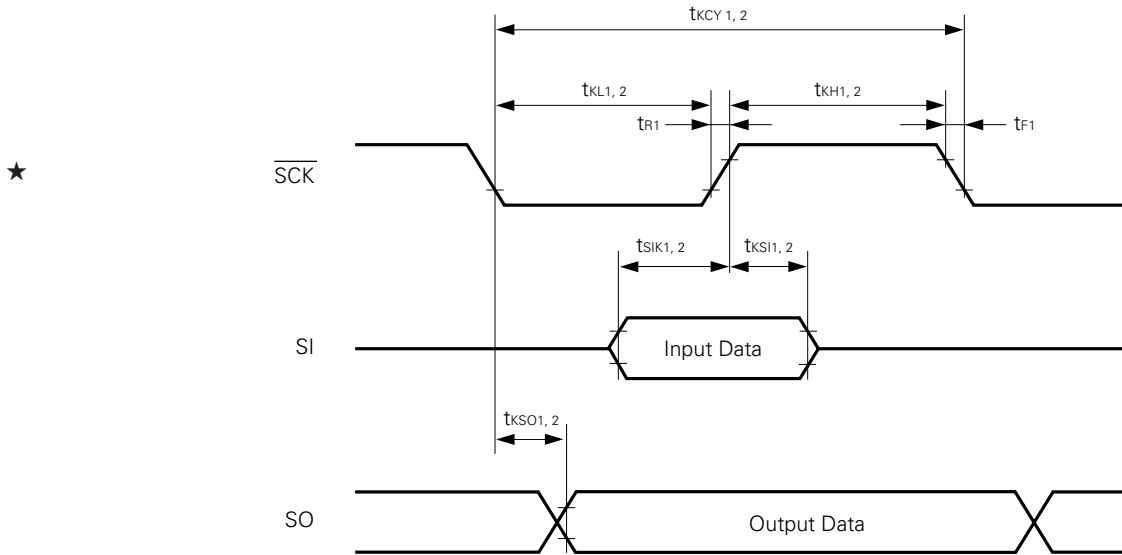


External data access (wait insertion):

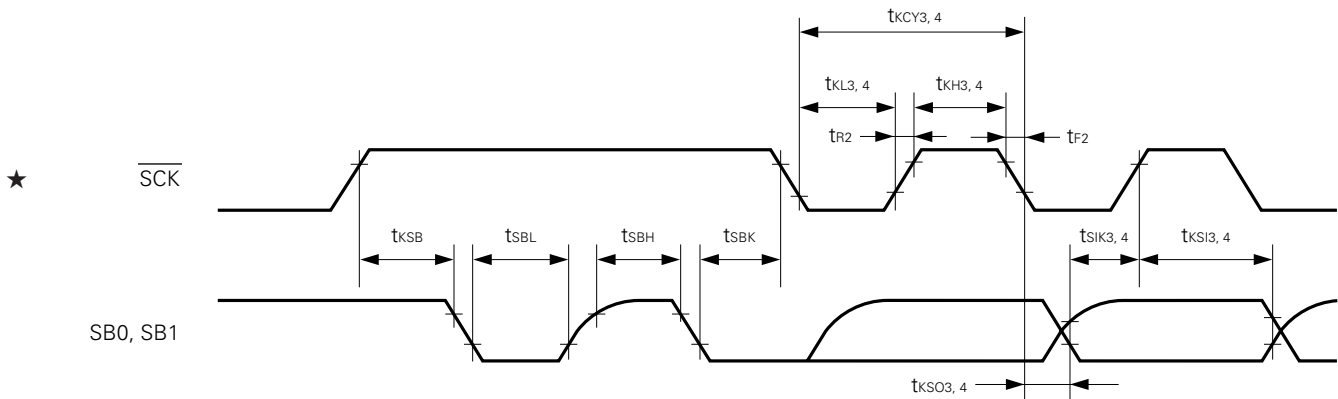


Serial Transfer Timing

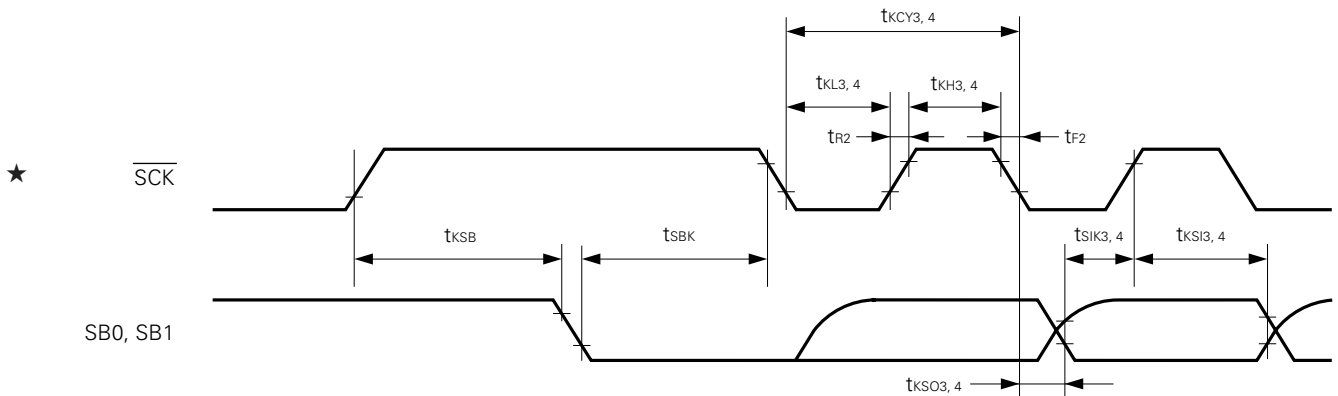
3-wire serial I/O mode:



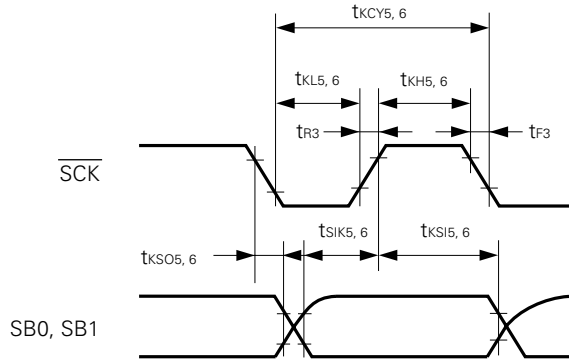
SBI mode (bus release signal transfer):



SBI mode (command signal transfer):

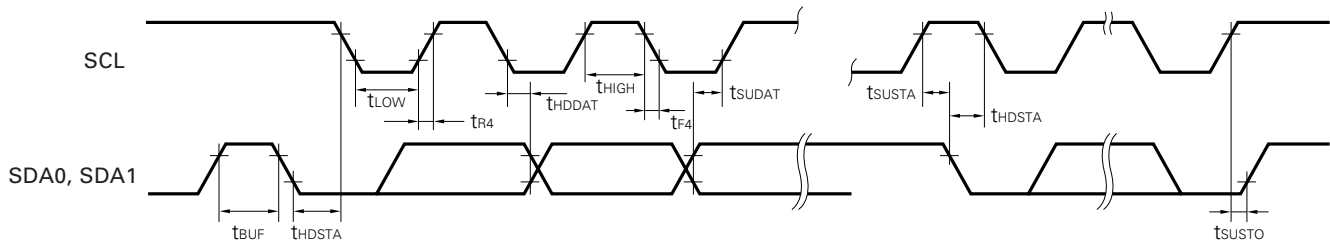


2-wire serial I/O mode:

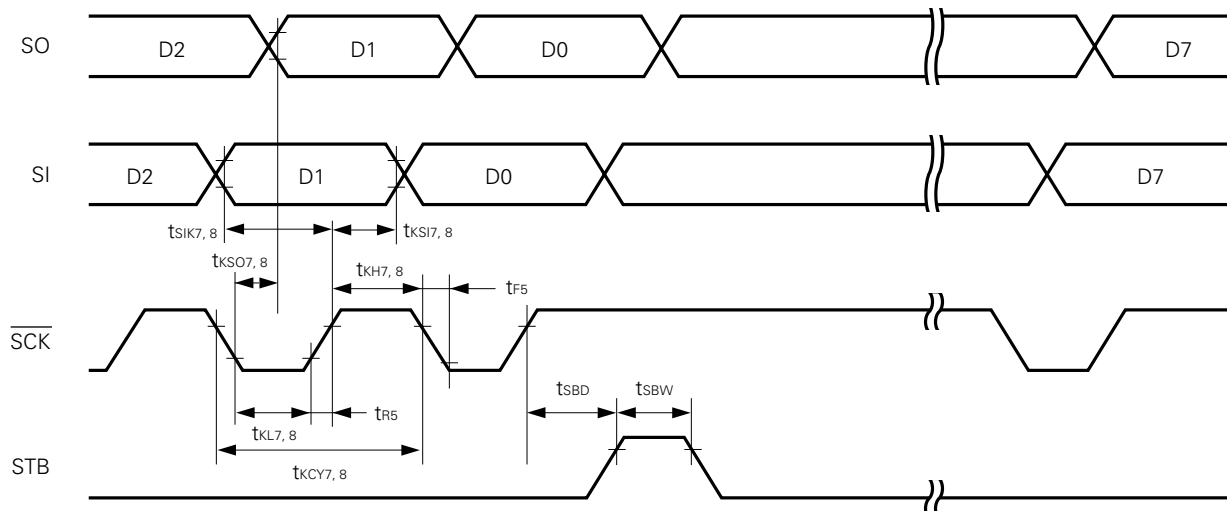


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I²C bus mode:

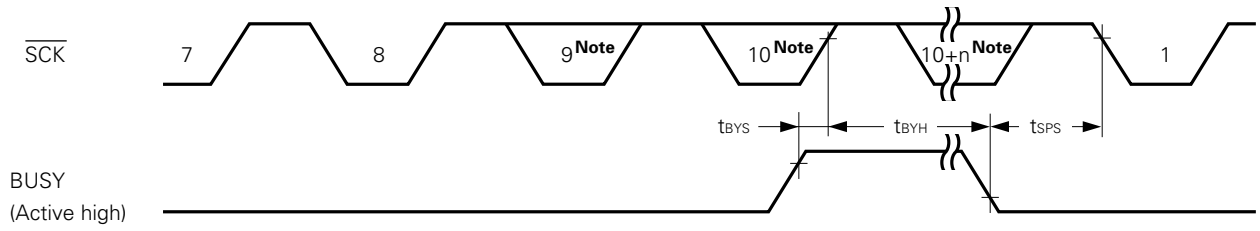


3-wire serial I/O mode with automatic transmit/receive function:



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3-wire serial I/O mode with automatic transmit/receive function (busy processing):



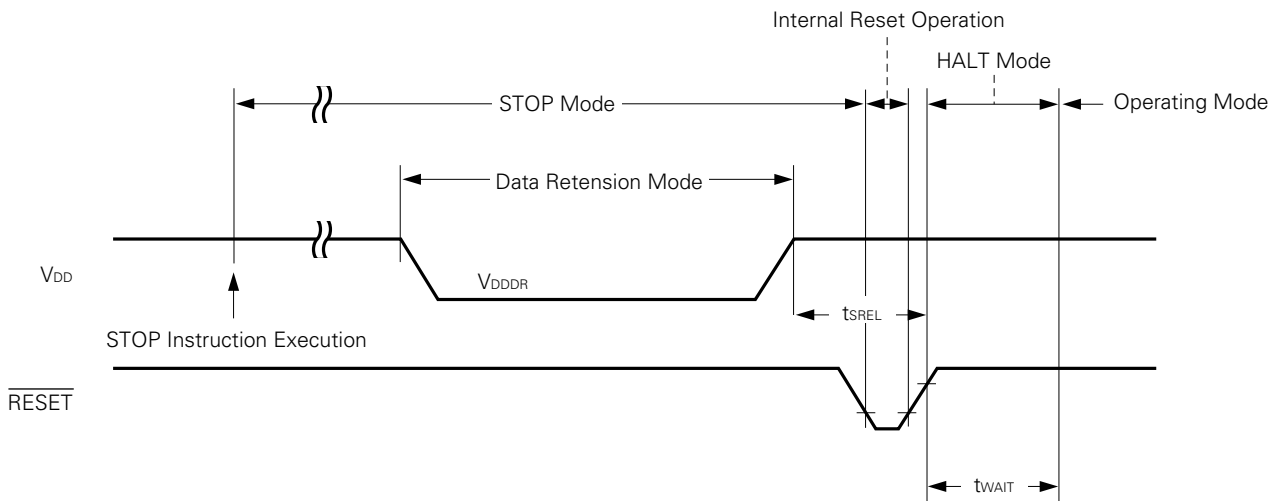
Note This signal is not driven low here; it is shown as such to indicate the timing.

DATA MEMORY STOP MODE LOW SUPPLY VOLTAGE DATA RETENTION CHARACTERISTICS (Ta = -40 to +85 °C)

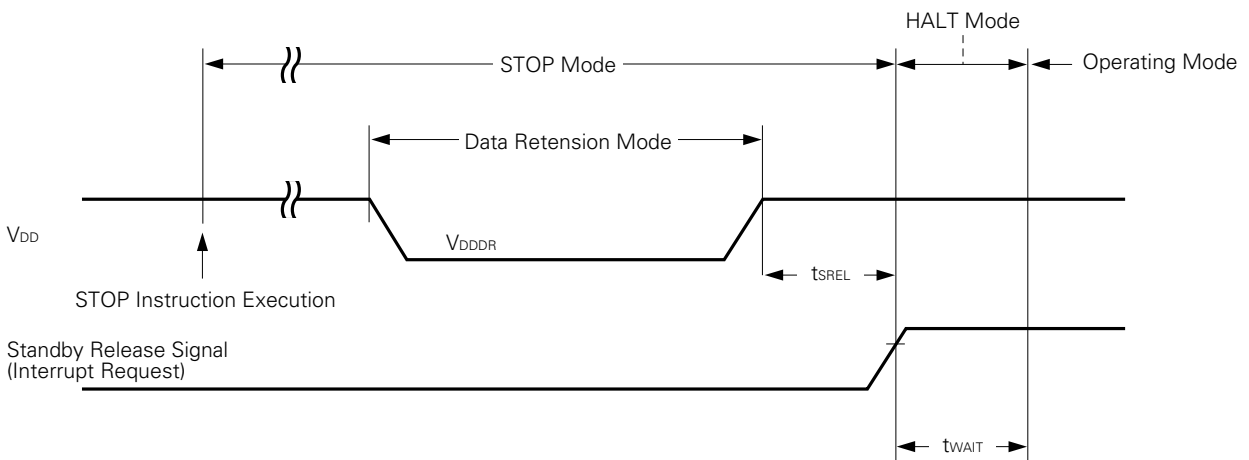
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Data retention supply voltage	V _{DDDR}		2.0		6.0	V
Data retention supply current	I _{DDDR}	V _{DDDR} = 2.0 V Subsystem clock stop and feed-back resistor disconnected		0.1	10	μA
Release signal set time	t _{SREL}		0			μs
Oscillation stabilization wait time	t _{WAIT}	Release by $\overline{\text{RESET}}$		2 ¹⁸ /f _x		ms
		Release by interrupt		Note		ms

Note In combination with bits 0 to 2 (OSTS0 to OSTS2) of oscillation stabilization time select register, selection of 2¹³/f_x and 2¹⁵/f_x to 2¹⁸/f_x is possible.

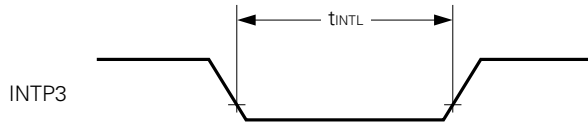
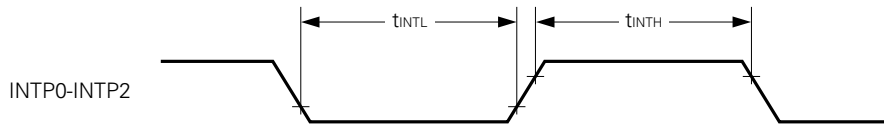
Data Retention Timing (STOP Mode Release by $\overline{\text{RESET}}$)



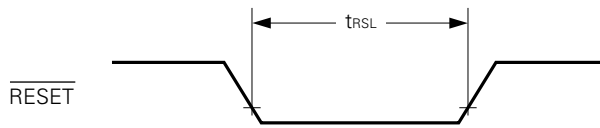
Data Retention Timing (Standby Release Signal: STOP Mode Release by Interrupt Signal)



Interrupt Input Timing

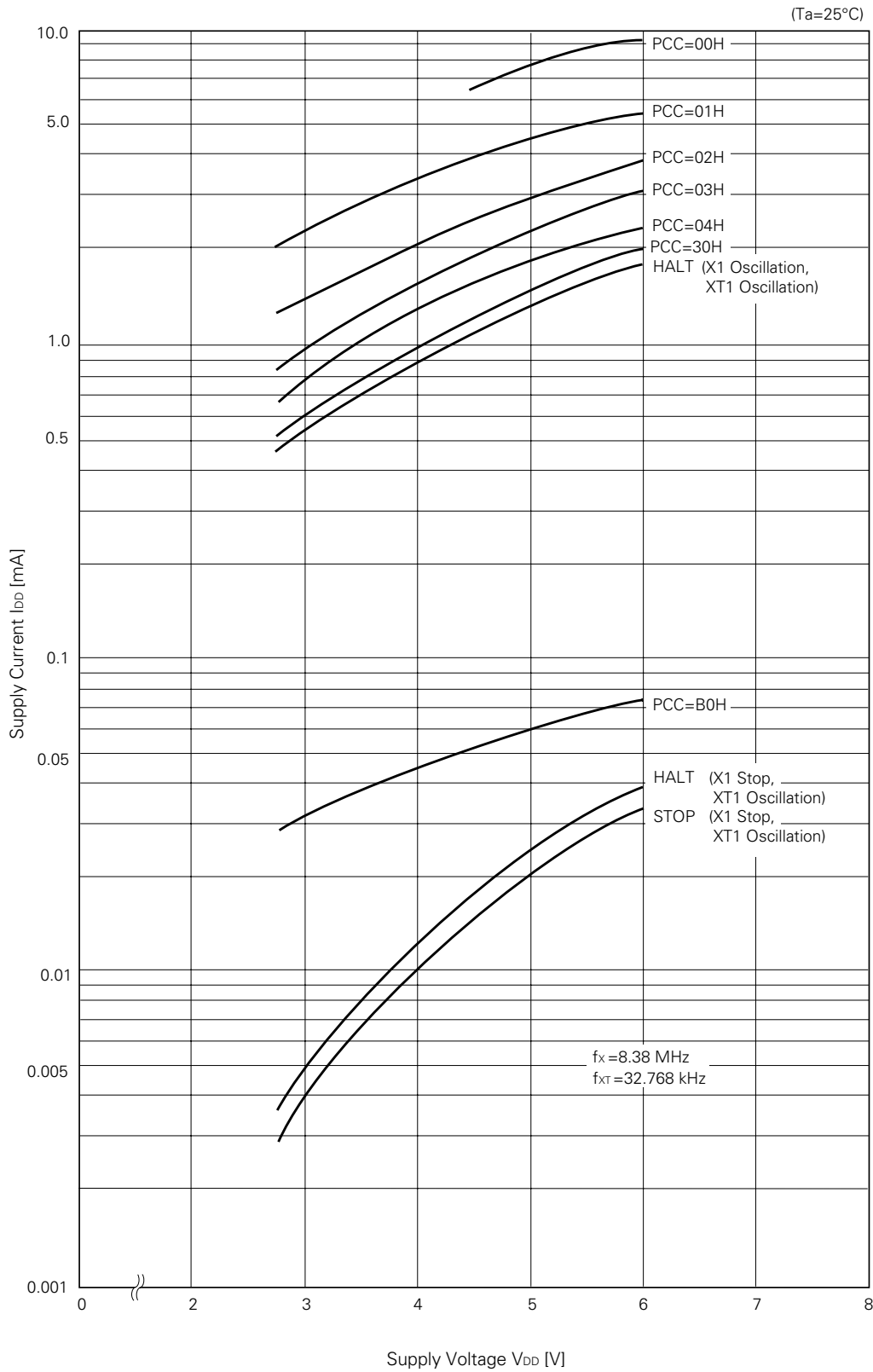


RESET Input Timing

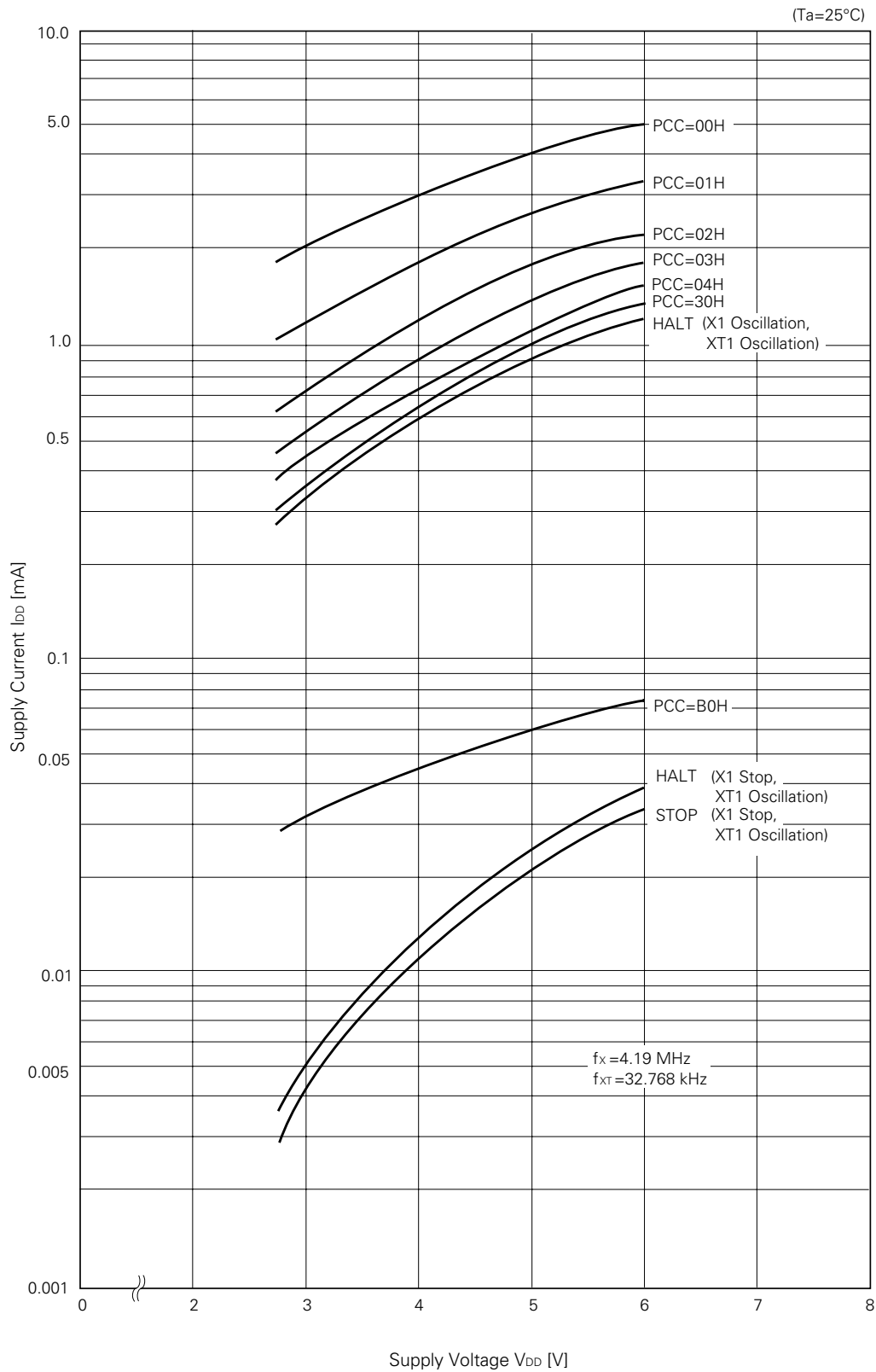


12. CHARACTERISTIC CURVE (REFERENCE VALUES)

I_{DD} vs V_{DD} (Main System Clock at 8.38 MHz)

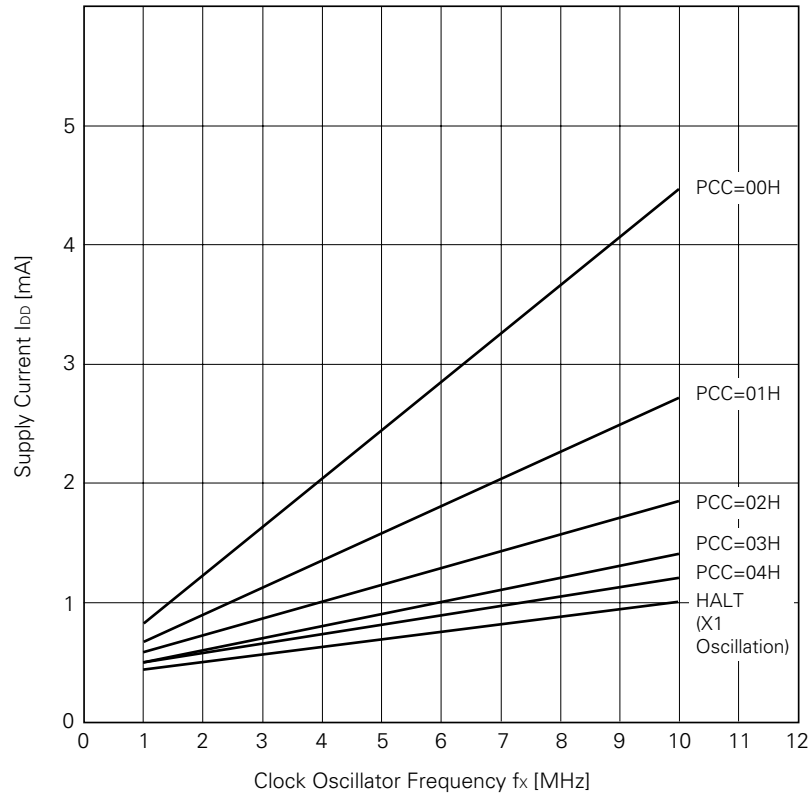


I_{DD} vs V_{DD} (Main System Clock at 4.19 MHz)



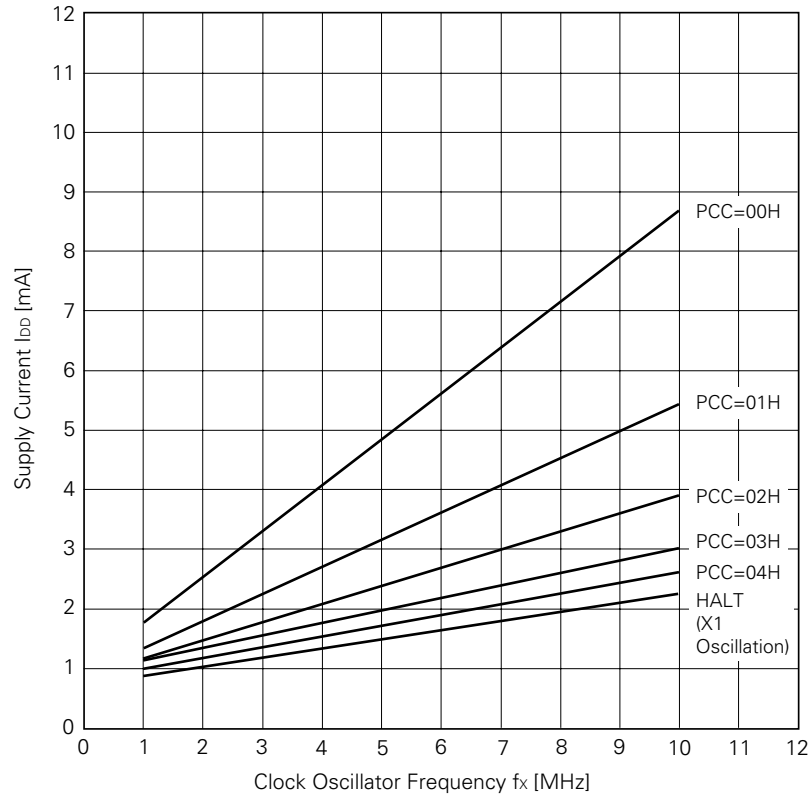
I_{DD} vs f_x

(V_{DD} = 3 V, T_a = 25°C)

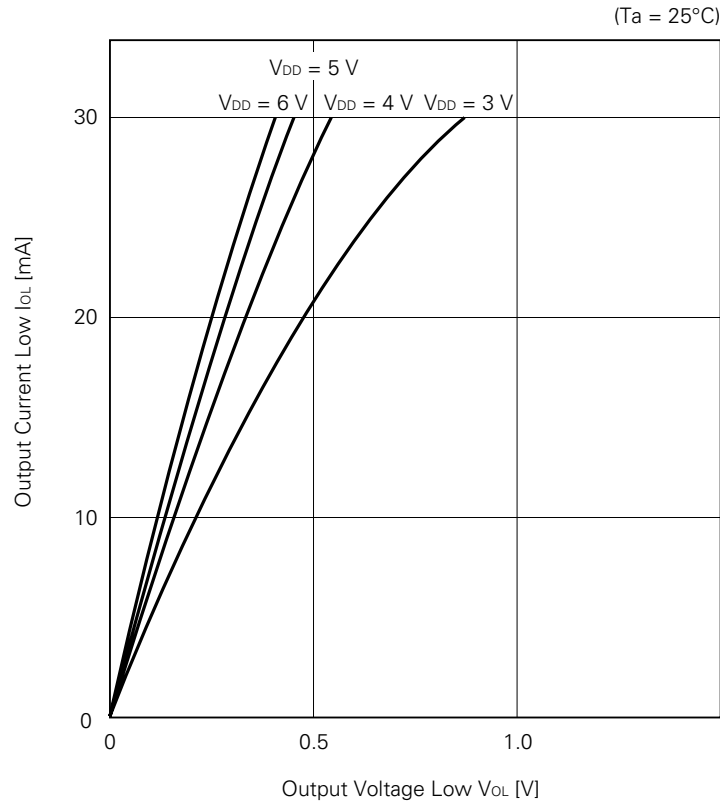


I_{DD} vs f_x

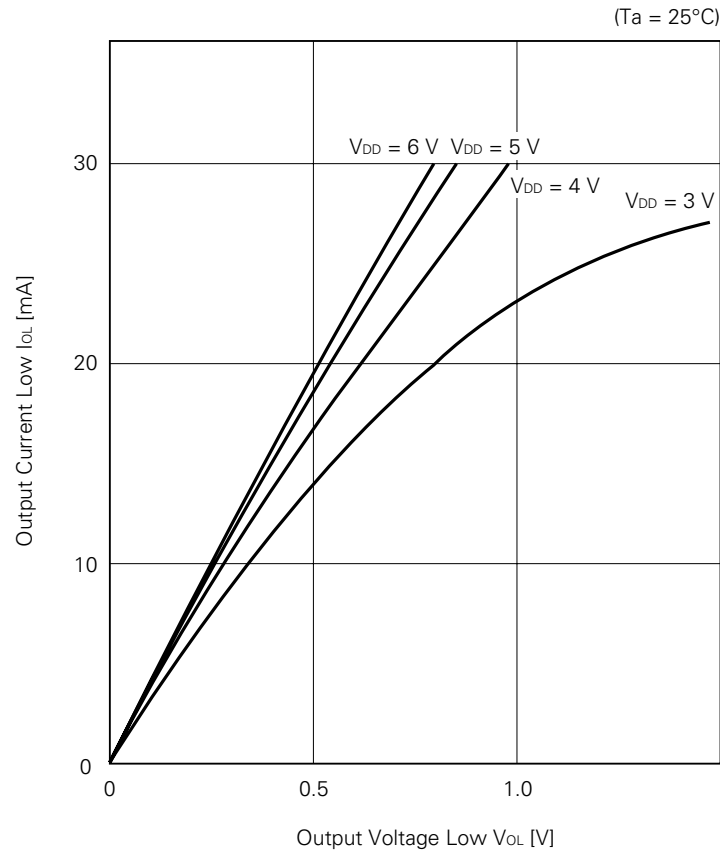
(V_{DD} = 5 V, T_a = 25°C)



V_{OL} vs I_{OL} (Port 0, 2 to 5, P64 to P67)

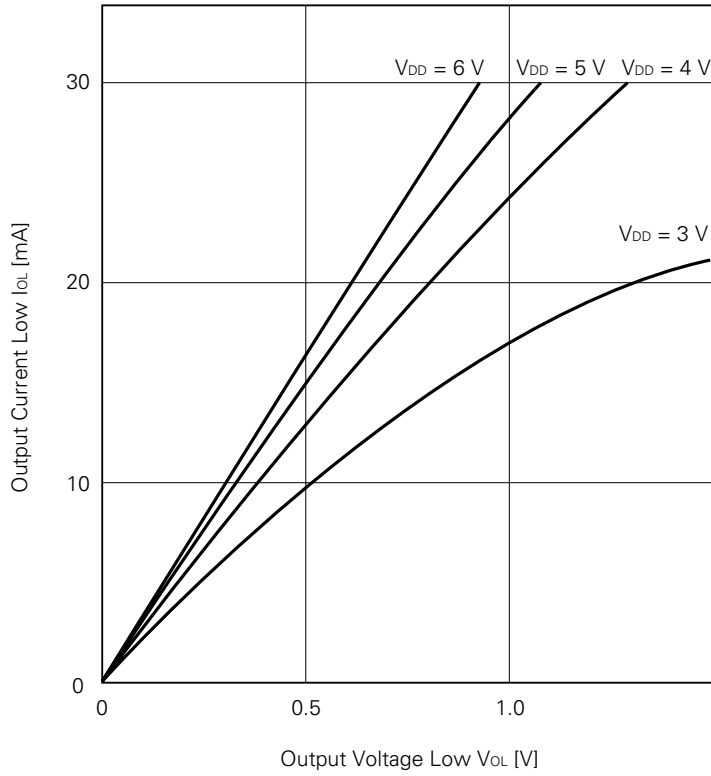


V_{OL} vs I_{OL} (Port 1)



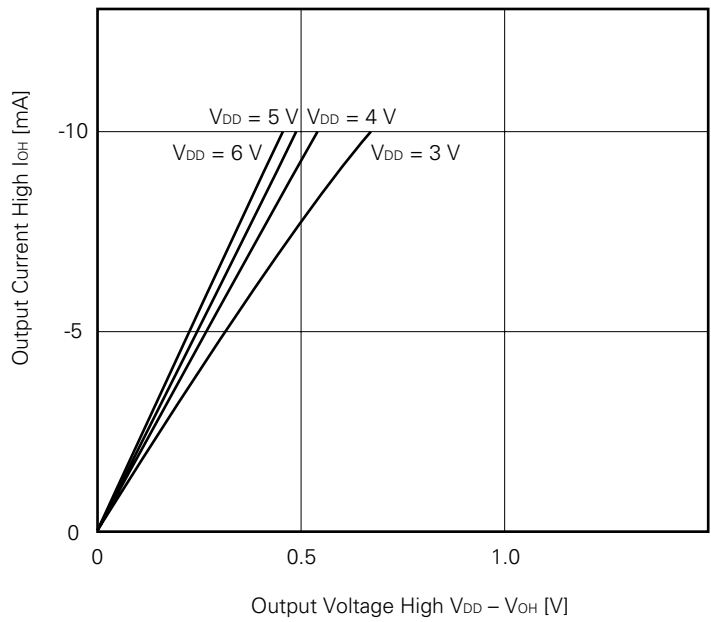
V_{OL} vs I_{OL} (P60 to P63)

(T_a = 25°C)



V_{OH} vs I_{OH} (Port 0 to 5, P64 to P67)

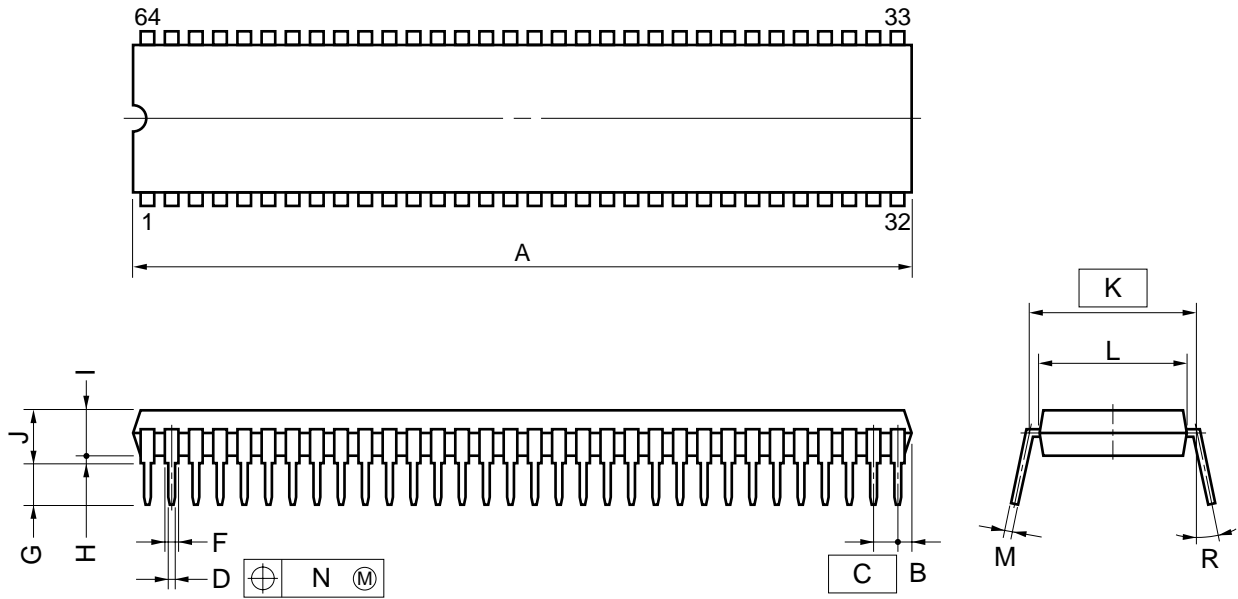
(T_a = 25 °C)



13. PACKAGE DRAWINGS

PACKAGE DRAWINGS OF MASS-PRODUCED PRODUCTS (1/2)

64 PIN PLASTIC SHRINK DIP (750 mil)



NOTE

- 1) Each lead centerline is located within 0.17 mm (0.007 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

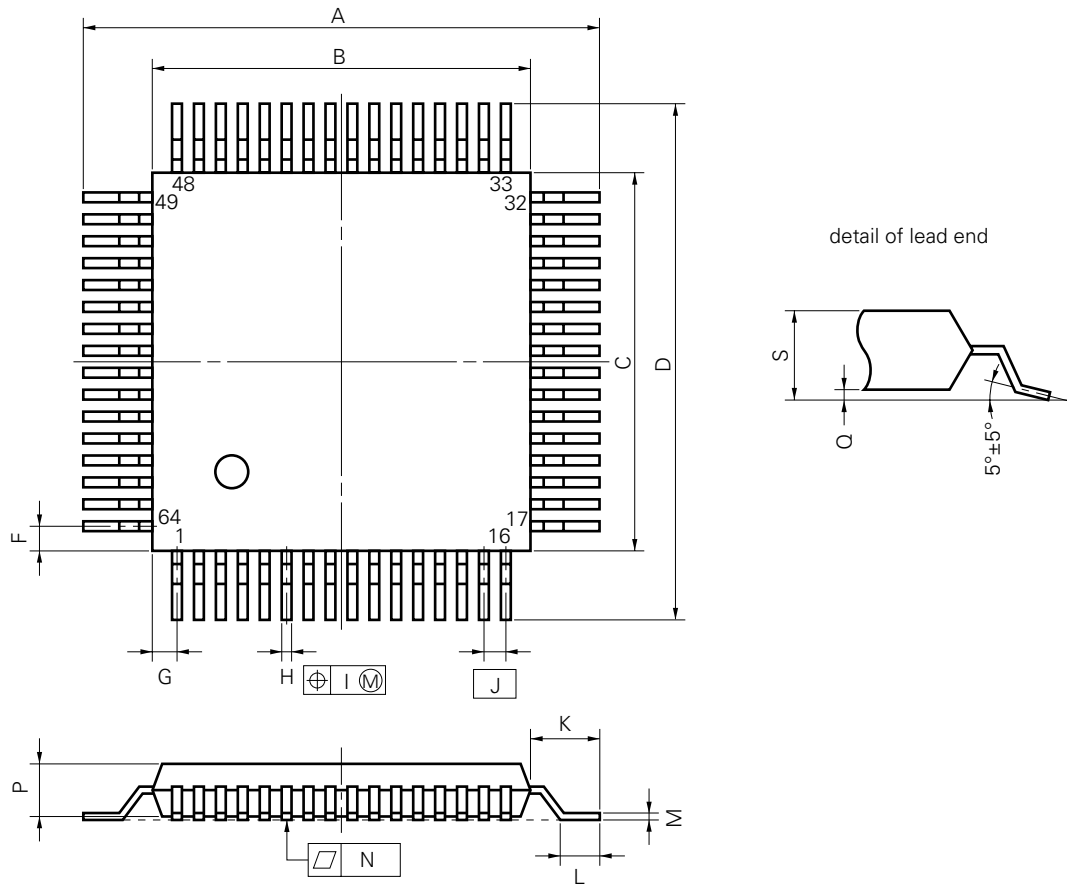
ITEM	MILLIMETERS	INCHES
A	58.68 MAX.	2.311 MAX.
B	1.78 MAX.	0.070 MAX.
C	1.778 (T.P.)	0.070 (T.P.)
D	0.50±0.10	0.020 ^{+0.004} _{-0.005}
F	0.9 MIN.	0.035 MIN.
G	3.2±0.3	0.126±0.012
H	0.51 MIN.	0.020 MIN.
I	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
K	19.05 (T.P.)	0.750 (T.P.)
L	17.0	0.669
M	0.25 ^{+0.10} _{-0.05}	0.010 ^{+0.004} _{-0.003}
N	0.17	0.007
R	0~15°	0~15°

P64C-70-750A,C-1

Caution The ES is different from the corresponding mass-produced products in shape and material. See "ES PACKAGE DRAWINGS (1/2) ."

PACKAGE DRAWINGS OF MASS-PRODUCED PRODUCTS (2/2)

64 PIN PLASTIC QFP (□14)



P64GC-80-AB8-3

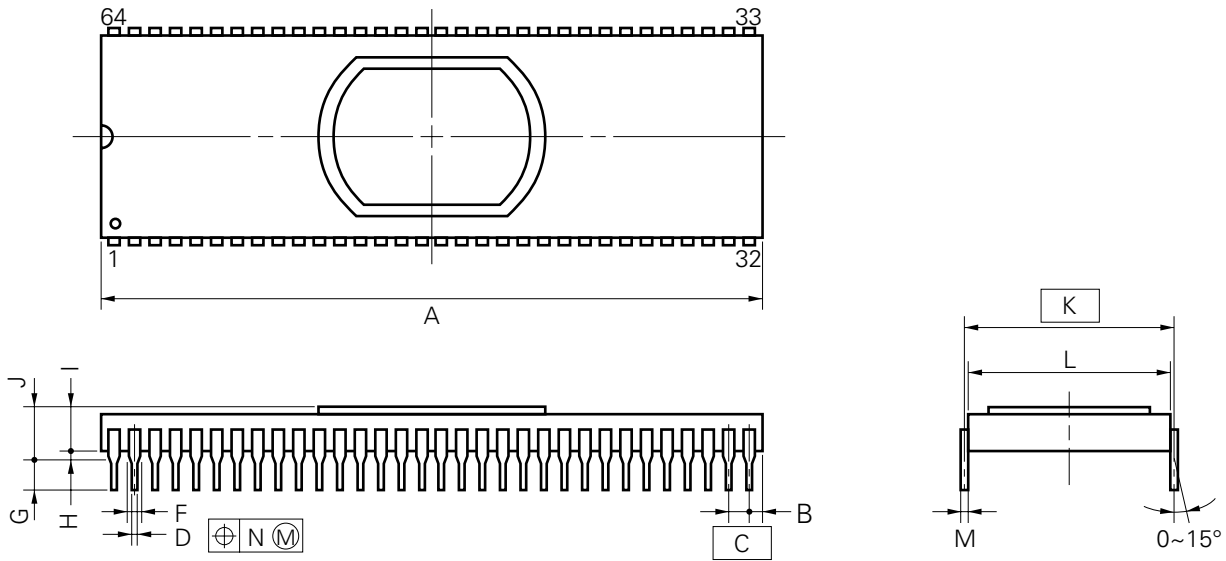
Note Each lead centerline is located within 0.15 mm (0.006 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	17.6±0.4	0.693±0.016
B	14.0±0.2	0.551 ^{+0.009} _{-0.008}
C	14.0±0.2	0.551 ^{+0.009} _{-0.008}
D	17.6±0.4	0.693±0.016
F	1.0	0.039
G	1.0	0.039
H	0.35±0.10	0.014 ^{+0.004} _{-0.005}
I	0.15	0.006
J	0.8 (T.P.)	0.031 (T.P.)
K	1.8±0.2	0.071±0.008
L	0.8±0.2	0.031 ^{+0.009} _{-0.008}
M	0.15 ^{+0.10} _{-0.05}	0.006 ^{+0.004} _{-0.003}
N	0.10	0.004
P	2.55	0.100
Q	0.1±0.1	0.004±0.004
S	2.85 MAX.	0.112 MAX.

Caution The ES is different from the corresponding mass-produced products in shape and material. See "ES PACKAGE DRAWINGS (2/2)."

ES PACKAGE DRAWINGS (1/2)

64PIN CERAMIC SHRINK DIP (SEAM WELD) (750 mil)



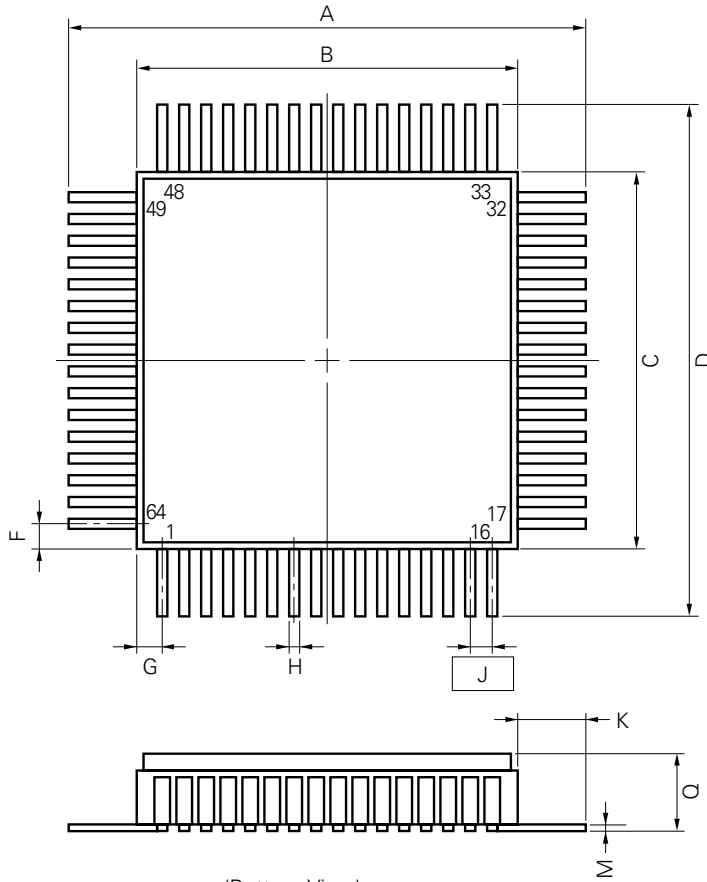
P64D-70-750A1

- Notes**
1. Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
 2. Item "K" to center of leads when formed parallel.

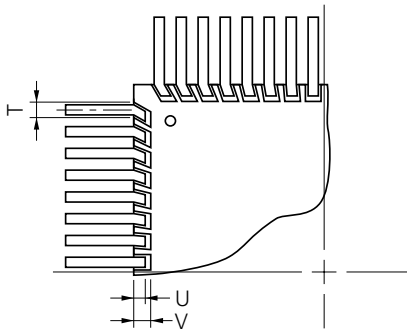
ITEM	MILLIMETERS	INCHES
A	58.16 MAX.	2.290 MAX.
B	1.521 MAX.	0.060 MAX.
C	1.778 (T.P.)	0.070 (T.P.)
D	0.46±0.05	0.018±0.002
F	0.8 MIN.	0.031 MIN.
G	3.5±0.3	0.138±0.012
H	1.02 MIN.	0.040 MIN.
I	3.14	0.124
J	5.08 MAX.	0.200 MAX.
K	19.05 (T.P.)	0.750 (T.P.)
L	18.8	0.740
M	0.25±0.05	0.010 ^{+0.002} _{-0.003}
N	0.25	0.01

ES PACKAGE DRAWINGS (2/2)

64 PIN CERAMIC QFP (14 × 14) (FOR ES)



(Bottom View)



X64B-80A-1

ITEM	MILLIMETERS	INCHES
A	22.0±0.4	0.866±0.016
B	14.0	0.551
C	14.0	0.551
D	22.0±0.4	0.866±0.016
F	1.0	0.039
G	1.0	0.039
H	0.32	0.013
J	0.8 (T.P.)	0.031 (T.P.)
K	4.0±0.15	0.157 ^{+0.007} _{-0.006}
M	0.25	0.01
Q	3.0 MAX.	0.119 MAX.
T	0.55	0.022
U	1.0	0.039
V	1.2	0.047

14. RECOMMENDED SOLDERING CONDITIONS

The μPD78011BY, μPD78012BY, μPD78013Y, and μPD78014Y should be soldered and mounted under the conditions recommended in the table below.

For detail of recommended soldering conditions, refer to the information document “**Semiconductor Device Mount Manual**” (IE-1207).

For soldering methods and conditions other than those recommended below, contact our sales personnel.

Table 14-1 Surface Mounting Type Soldering Conditions

- (1) μPD78011BYGC-xxx-AB8 : 64-Pin Plastic QFP (14 × 14 mm)
- μPD78012BYGC-xxx-AB8 : 64-Pin Plastic QFP (14 × 14 mm)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C Duration: 30 sec. max. (at 210°C or above) Number of times: Twice max. <precautions> (1) The second reflow should be started after the first reflow device temperature has returned to the ordinary state. (2) Flux washing must not be performed by the use of water after the first reflow.	IR35-00-2
VPS	Package peak temperature: 215°C Duration: 40 sec. max. (at 200°C or above) Number of times: Twice max. <precautions> (1) The second reflow should be started after the first reflow device temperature has returned to the ordinary state. (2) Flux washing must not be performed by the use of water after the first reflow.	VP15-00-2
Partial heating method	Terminal temperature: 300°C max. Duration: 3 sec. max. (per device side)	—

Caution Use more than one soldering method should be avoided (except for partial heating method).

- (2) μPD78013YGC-xxx-AB8 : 64-Pin Plastic QFP (14 × 14 mm)
- μPD78014YGC-xxx-AB8 : 64-Pin Plastic QFP (14 × 14 mm)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C Duration: 30 sec. max. (at 210°C or above) Number of times: Twice max. <precautions> (1) The second reflow should be started after the first reflow device temperature has returned to the ordinary state. (2) Flux washing must not be performed by the use of water after the first reflow.	IR35-00-2
VPS	Package peak temperature: 215°C Duration: 40 sec. max. (at 200°C or above) Number of times: Twice max. <precautions> (1) The second reflow should be started after the first reflow device temperature has returned to the ordinary state. (2) Flux washing must not be performed by the use of water after the first reflow.	VP15-00-2
Wave soldering	Solder bath temperature: 260°C max. Duration: 10 sec. max. Number of times: Once Preliminary heat temperature: 120°C max. (Package surface temperature)	WS60-00-1
Partial heating method	Terminal temperature: 300°C max. Duration: 3 sec. max. (per device side)	—

★

★

★

Caution Use of more than one soldering method should be avoided (except for partial heating method).

Table 14-2 Insertion Type Soldering Conditions

- μPD78011BYCW-xxx : 64-pin plastic shrink DIP (750mil)
- μPD78012BYCW-xxx : 64-pin plastic shrink DIP (750mil)
- μPD78013YCW-xxx : 64-pin plastic shrink DIP (750mil)
- μPD78014YCW-xxx : 64-pin plastic shrink DIP (750mil)

Soldering Method	Soldering Conditions
Wave soldering (terminal only)	Solder bath temperature: 260°C max., Duration: 10 sec. max.
Partial heating method	Terminal temperature: 300°C max., Duration: 3 sec. max. (for each pin)

★

Caution Apply wave soldering to terminals only. See to it that the jet solder does not contact with the chip directly.

APPENDIX A. DEVELOPMENT TOOLS

The following development tools are available for system development using the μPD78011BY, μPD78012BY, μPD78013Y, and μPD78014Y.

Language Processors

RA78K/0Notes 1-3	78K/0 series common assembler package
CC78K/0Notes 1-3	78K/0 series common C compiler package
★ DF78014Notes 1-3	Device file for μPD78014 sub-series
CC78K/0-LNotes 1-3	78K/0 series common C compiler library source file

PROM Write Tools

PG-1500	PROM programmer
PA-78P014CW PA-78P014GC	Programmer adapter connected to PG-1500
PG-1500 controllerNotes 1, 2	PG-1500 control program

Debugging Tools

IE-78000-R	78K/0 series common in-circuit emulator
IE-78000-R-BK	78K/0 series common break board
IE-78014-R-EM	Evaluation emulation board for μPD78002 and μPD78014 sub-series
EP-78240CW-R EP-78240GC-R	Emulation probe common with μPD78244 sub-series
EV-9200GC-64	Socket mounted onto user system board for 64-pin plastic QFP
SD78K/0Notes 1, 2	IE-78000-R screen debugger
★ SM78k/0Notes 3-6	78K/0 series system simulator
DF78014Notes 1-5	Device file for μPD78014 sub-series

Real-Time OS

RX78K/0Notes 1-3	78K/0 series real-time OS
★ MX78K/0Notes 1-3, 6	78K/0 series OS

Fuzzy Inference Development Support System

FE9000Note 1 / FE9200Note 5	Fuzzy knowledge data creation tool
FT9080Note 1 / FT9085Note 2	Translator
FI78K0Notes 1, 2	Fuzzy inference module
FD78K0Notes 1, 2	Fuzzy inference debugger

Notes 1. PC-9800 series (MS-DOS™) based

2. IBM PC/AT™ (PC DOS™) based

★ 3. HP9000 series 300™ and HP9000 series 700™(HP-UX™) based, SPARCstation™ (Sun OS™) based and EWS-4800 series™ (EWS-UX/V™) based

4. PC-9800 series (MS-DOS + Windows™) based

5. IBM PC/AT (PC DOS + Windows) based

6. Under development

Remarks 1. See “78K/0 Series Selection Guide (IF-1185)” for development tools created by the third parties.

★ 2. The RA78K/0, CC78K/0, SD78K/0, and SM78K/0 are used with the DF78014.

APPENDIX B. RELATED DOCUMENTATION



Device Related Documentation

Document Name		Document No. (Japanese)	Document No. (English)
User's Manual		IEU-780	IEU-1343
78K/0 Series User's Manual, Instruction		IEU-849	IEU-1372
Application Note	Basic I	IEA-715	IEA-1288
	Basic II	IEA-740	IEA-1299
	Floating Point Arithmetic Program	IEA-718	IEA-1289

Development Tool Documentation (User's Manual)

Document Name		Document No. (Japanese)	Document No. (English)
RA78K Series Assembler Package	Operation	EEU-809	EEU-1399
	Language	EEU-815	EEU-1404
RA78K Series Structured Assembler Preprocessor		EEU-817	EEU-1402
CC78K Series C Compiler	Operation	EEU-656	EEU-1280
	Language	EEU-655	EEU-1284
PG-1500 PROM Programmer		EEU-651	EEU-1335
PG-1500 Controller		EEU-704	EEU-1291
IE-78000-R		EEU-810	EEU-1398
IE-78000-R-BK		EEU-867	EEU-1427
IE-78014-R-EM		EEU-805	EEU-1400
SD78K/0 Screen Debugger	Basic	EEU-852	EEU-1414
	Reference	EEU-816	EEU-1413

Documents Related to Built-in Software (User's Manual)

Document Name	Document No. (Japanese)	Document No. (English)
Tool for Creating Fuzzy Knowledge Data	EEU-829	EEU-1438
78K/0, 78K/II, and 87AD Series Fuzzy Interface Development Support System, Translator	EEU-862	EEU-1444

Other Documents

Document Name	Document No. (Japanese)	Document No. (English)
Package Manual	IEI-635	IEI-1213
Surface Mount Technology Manual	IEI-616	IEI-1207
Quality Grades on Semiconductor Devices	IEI-620	IEI-1209
Semiconductor Devices Quality Control Guarantee Guide	MEI-603	MEI-1202

Caution The contents of the above documents are subject to change without notice. The latest documents should be used for design, etc.

Cautions on CMOS Devices

① **Countermeasures against static electricity for all MOSs**

Caution When handling MOS devices, take care so that they are not electrostatically charged.

Strong static electricity may cause dielectric breakdown in gates. When transporting or storing MOS devices, use conductive trays, magazine cases, shock absorbers, or metal cases that NEC uses for packaging and shipping. Be sure to ground MOS devices during assembling. Do not allow MOS devices to stand on plastic plates or do not touch pins. Also handle boards on which MOS devices are mounted in the same way.

② **CMOS-specific handling of unused input pins**

Caution Hold CMOS devices at a fixed input level.

Unlike bipolar or NMOS devices, if a CMOS device is operated with no input, an intermediate-level input may be caused by noise. This allows current to flow in the CMOS device, resulting in a malfunction. Use a pull-up or pull-down resistor to hold a fixed input level. Since unused pins may function as output pins at unexpected times, each unused pin should be separately connected to the V_{DD} or GND pin through a resistor.

If handling of unused pins is documented, follow the instructions in the document.

③ **Statuses of all MOS devices at initialization**

Caution The initial status of a MOS device is unpredictable when power is turned on.

Since characteristics of a MOS device are determined by the amount of ions implanted in molecules, the initial status cannot be determined in the manufacture process. NEC has no responsibility for the output statuses of pins, input and output settings, and the contents of registers at power on. However, NEC assures operation after reset and items for mode setting if they are defined.

When you turn on a device having a reset function, be sure to reset the device first.

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Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.